FUJITSU SEMICONDUCTOR
DATA SHEET

DS07-12516-3E

8-bit Proprietary Microcontroller

CMOS

F²MC-8L MB89870 Series

MB89875/P875/PV870

■ DESCRIPTION

The MB89870 series is a line of single-chip microcontrollers. In addition to a compact instruction set, the microcontrollers contain a variety of peripheral functions such as dual-clock control system, five operating speed control stages, timers, a PWM timer, a serial interface, an A/D converter, an external interrupt, an LCD controller/driver, and a watch prescaler.

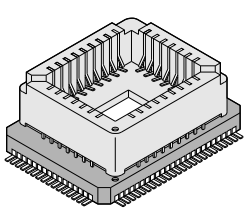
■ FEATURES

- F²MC-8L family CPU core
- Dual-clock control system
- Maximum memory space: 64 Kbytes
- Minimum execution time: 0.4 µs/10 MHz
- Interrupt processing time: 3.6 µs/10 MHz
- I/O ports: max. 45 channels
- 21-bit time-base timer
- 8-bit PWM timer: 1 channel, 1 output channel
- 8/16-bit timer/counter: 2 channels (16 bits × 1 channel)
- 8-bit serial I/O: 1 channel
- 10-bit A/D converter: 8 channels
- OP amp: 4 channels
- External interrupt (wake-up function): 8 channels

(Continued)

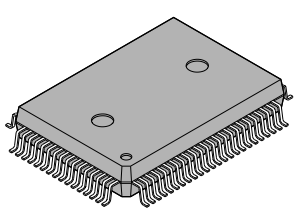
■ PACKAGE

80-pin Ceramic MQFP



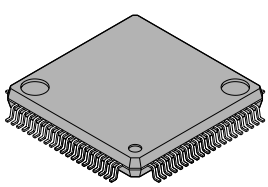
(MQP-80C-P01)

80-pin Plastic QFP



(FPT-80P-M06)

80-pin Plastic SQFP



(FPT-80P-M05)

MB89870 Series

(Continued)

- Watch prescaler (15 bits)
- LCD controller/driver: 16 to 24 segments × 2 to 4 commons
- Power-on reset function
- Low-power consumption modes (subclock mode, watch mode, sleep mode, and stop mode)
- QFP-80 (0.80-mm pitch) and SQFP-80 (0.50-mm pitch) package

■ PRODUCT LINEUP

Parameter \ Part number	MB89875	MB89P875	MB89PV870
Classification	Mass production product (mask ROM product)	One-time PROM product	Piggyback/evaluation product (for development)
ROM size	16 K × 8 bits (internal mask ROM)	16 K × 8 bits (internal PROM)	32 K × 8 bits (external ROM)
RAM size	512 × 8 bits		1K × 8 bits
LCD display RAM	12 × 8 bits		
CPU functions	Number of instructions: 136 Instruction bit length: 8 bits Instruction length: 1 to 3 bytes Data bit length: 1, 8, 16 bits Minimum execution time: 0.4 µs/10 MHz to 6.4 µs/10 MHz, 62.5 µs/32.768 kHz Interrupt processing time: 3.6 µs/10 MHz to 57.6 µs/10 MHz, 562.5 µs/32.768 kHz		
Ports	I/O ports (CMOS): 45 (42 ports also serve as peripherals and 8 ports are also an N-ch open-drain type.)		
8-bit PWM timer	8-bit reload timer operation (toggled output capable, operating clock cycle: 0.4 µs to 3.3 ms) × 1 channel 7/8-bit resolution PWM operation (conversion cycle: 51.2 µs to 839 ms) × 1 channel		
Timers	8-bit timer operation (operating clock cycle) × 2 channels 16-bit timer operation (operating clock cycle) × 1 channel		
8-bit Serial I/O	8 bits LSB first/MSB first selectability One clock selectable from four operation clocks (one external shift clock, three internal shift clocks: 0.8 µs, 3.2 µs, 12.8 µs)		
LCD controller	24 segments × 4 commons		
10-bit A/D converter	10-bit resolution × 8 channels A/D conversion mode (conversion time: 13.2 µs) Sense mode (conversion time: 7.2 µs)		
OP amps	4 channels The output can be used for A/D conveter input.		

(Continued)

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Parameter \ Part number	MB89875	MB89P875	MB89PV870
External interrupt	8 independent channels (edge selection, interrupt vector, and source flag) Rising edge/falling edge selectability (4 channels) Rising edge/falling edge/both edges selectability (4 channels) Used also for wake-up from stop/sleep mode. (Edge detection is also permitted in stop mode.)		
Standby mode	Subclock mode, sleep mode, watch mode, and stop mode		
Process	CMOS		
Operating voltage*	2.2 V to 6.0 V	2.7 V to 6.0 V	
EPROM for use			MBM27C256A-20TV

* : Varies with conditions such as the operating frequency. (See section "■ Electrical Characteristics.")

■ PACKAGE AND CORRESPONDING PRODUCTS

Package	MB89875 MB89P875	MB89PV870
FPT-80P-M06	○	×
FPT-80P-M05	○	×
MQP-80C-P01	×	○

○ : Available × : Not available

Note: For more information about each package, see section "■ Package Dimensions."

■ DIFFERENCES AMONG PRODUCTS

1. Memory Size

Before evaluating using the piggyback product, verify its differences from the product that will actually be used. Take particular care on the folowing points:

- On the MB89P875, the program area starts from address 8006_H but on the MB89PV870 and MB89875 starts from 8000_H.
  (On the MB89P875, addresses $BFF0_H$ to $BFF6_H$ comprise the option setting area, option settings can be read by readng these addresses. On the MB89PV870 and MB89875, addresses 8000_H to 8006_H could also be used as a program ROM. However, do not use these addresses in order to maintain compatibility of the MB89P875.)

2. Current Consumption

- In the case of the MB89PV870, add the current consumed by the EPROM which is connected to the top socket.
- When operated at low speed, the product with an OTPROM (one-time PROM) or an EPROM will consume more current than the product with a mask ROM.
  However, the current consumption in sleep/stop modes is the same. (For more information, see sections "■ Electrical Characteristics" and "■ Example Characteristics.")

3. Mask Options

Functions that can be selected as options and how to designate these options vary by the product.

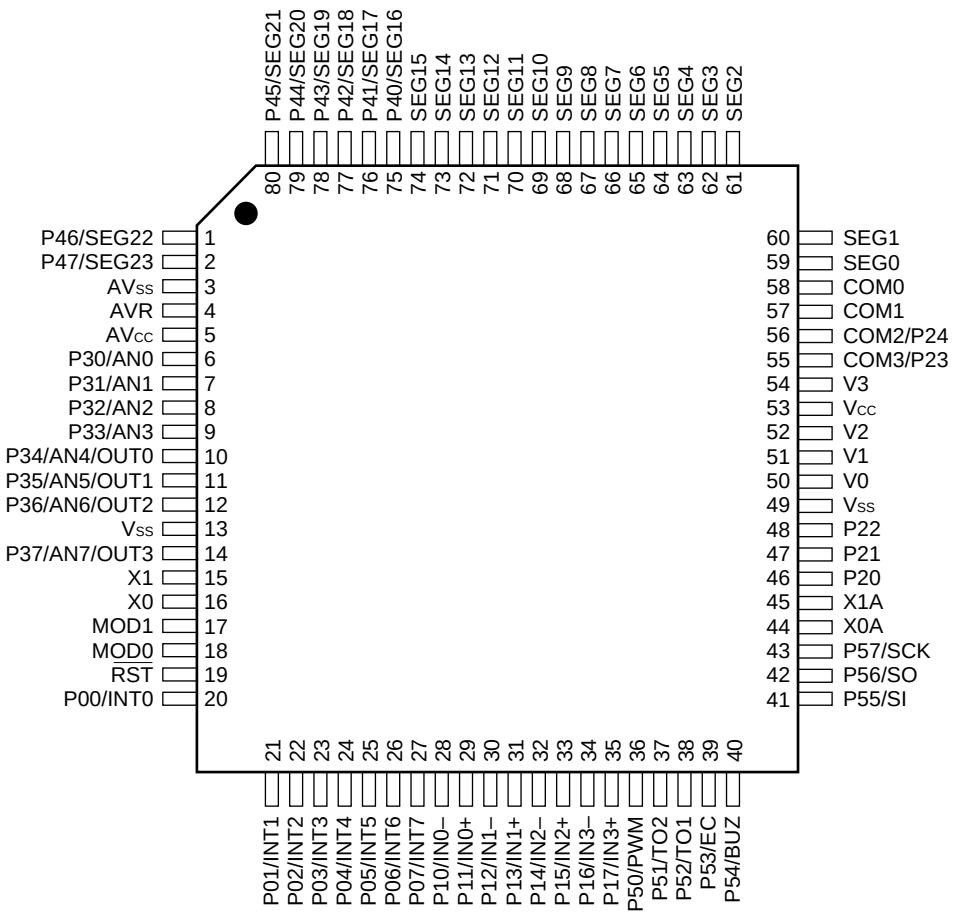
Before using options check section "■ Mask Options."

Take particular care on the following points:

- A pull-up resistor cannot be selectable for P30 to P37 if they are used as the analog input pin for an A/D converter.
- A pull-up resistor cannot be selectable for P10 to P17, and P34 to P37 if an OP amp is used.
- A pull-up resistor is not selectable for P40 to P47 and P23, P24 if they are used as LCD pins.
- Options are fixed on the MB89PV870.

■ PIN ASSIGNMENT

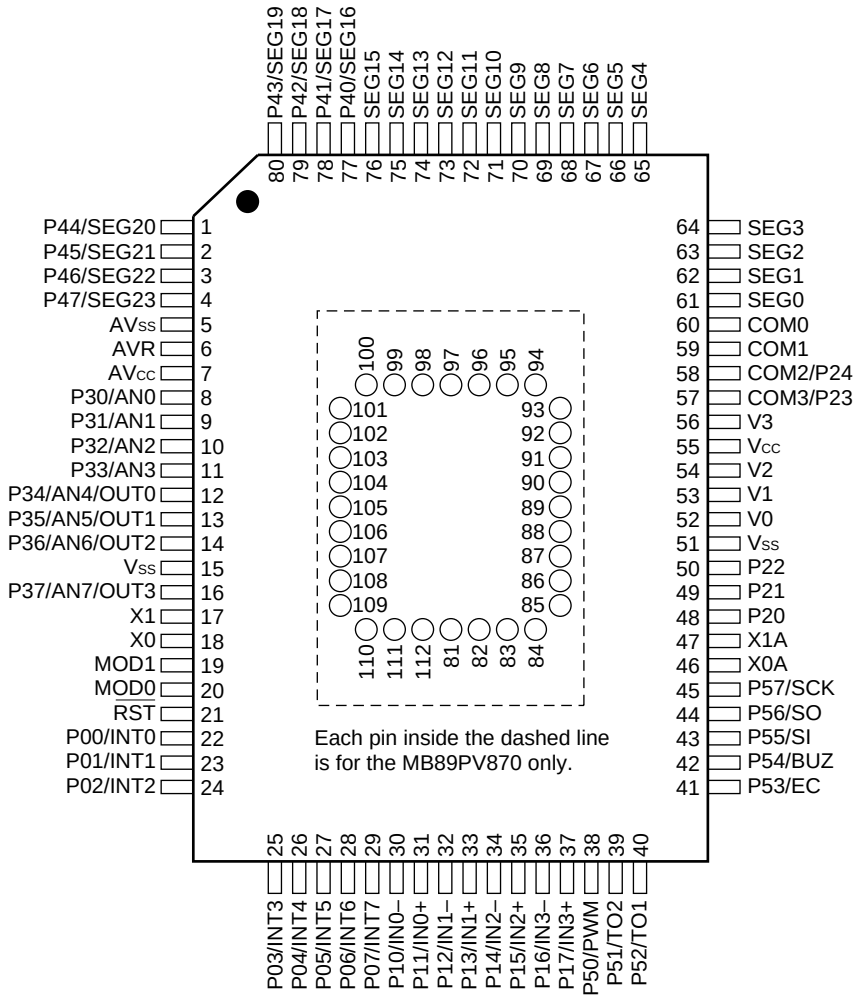
(Top view)



(FPT-80P-M05)

MB89870 Series

(Top view)



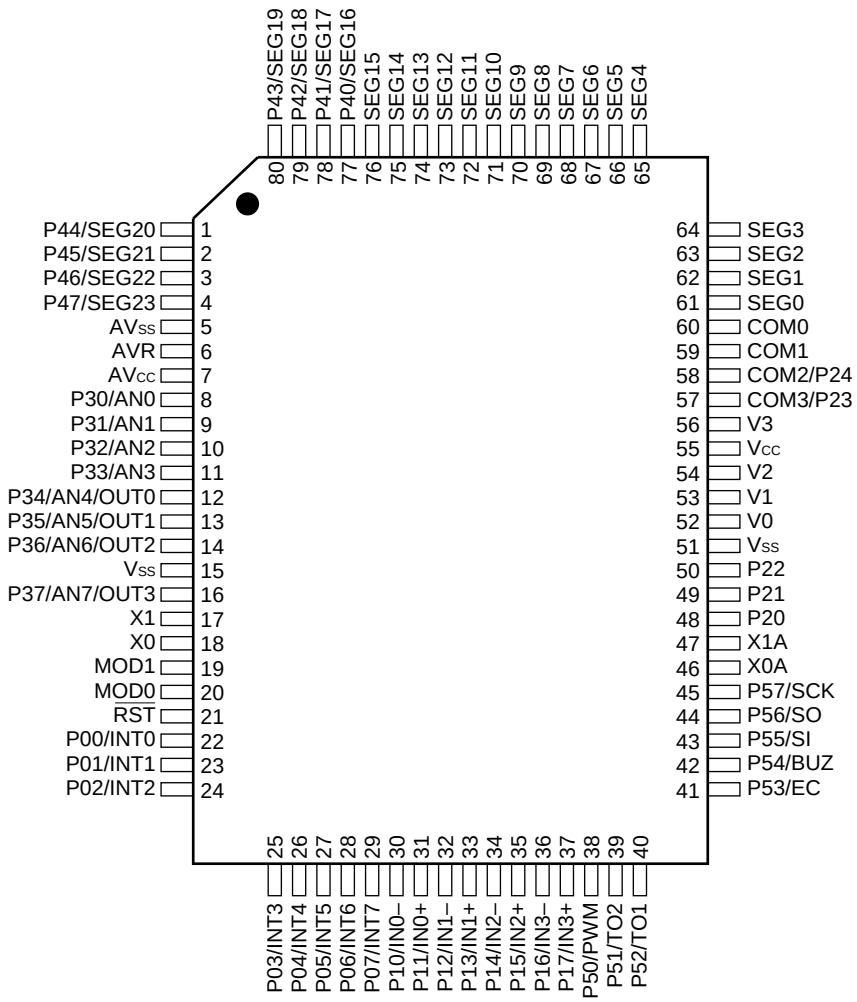
(MQP-80C-P01)

- **Pin assignment on package top (MB89PV870 only)**

Pin no.	Pin name	Pin no.	Pin name	Pin no.	Pin name	Pin no.	Pin name
81	N.C.	89	A2	97	N.C.	105	$\overline{OE}$
82	V_{PP}	90	A1	98	O4	106	N.C.
83	A12	91	A0	99	O5	107	A11
84	A7	92	N.C.	100	O6	108	A9
85	A6	93	O1	101	O7	109	A8
86	A5	94	O2	102	O8	110	A13
87	A4	95	O3	103	$\overline{CE}$	111	A14
88	A3	96	V_{SS}	104	A10	112	V_{CC}

N.C.: Internally connected. Do not use.

(Top view)



(FPT-80P-M06)

MB89870 Series

■ PIN DESCRIPTION

Pin no.		Pin name	Circuit type	Function
SQFP*1,	QFP*2 MQFP*3			
44	46	X0A	B	Subclock crystal oscillator pins (32.768 kHz)
45	47	X1A		
15	17	X1	A	Main clock crystal oscillator pins (max. 10 MHz)
16	18	X0		
17	19	MOD1	C	Operating mode selection pins Connect to V_{SS} (GND) when using.
18	20	MOD0		
19	21	$\overline{RST}$	J	Reset I/O pin “L” is output from this pin by an internal source. The internal circuit is initialized by the input of “L”.
20 to 27	22 to 29	P00/INT0 to P07/INT7	D	General-purpose I/O ports Also serve as an external interrupt input (wake-up function). External interrupt input is hysteresis input.
28, 29, 30, 31, 32, 33, 34, 35	30, 31, 32, 33, 34, 35, 36, 37	P10/IN0–, P11/IN0+, P12/IN1–, P13/IN1+, P14/IN2–, P15/IN2+, P16/IN3–, P17/IN3+	E	General-purpose I/O ports Also serve as the input for the OP amp
46 to 48	48 to 50	P20 to P22	F	General-purpose I/O ports
6 to 9	8 to 11	P30/AN0 to P33/AN3	E	General-purpose I/O ports Also serve as the input for the A/D converter.
10 to 14	12 to 16	P34/AN4/OUT0 to P37/AN7/OUT3	G	General-purpose I/O ports Also serve as the A/D converter input and the output for the OP amp.
75 to 80, 1,2	77 to 80, 1 to 4	P40/SEG16 to P47/SEG23	H	General-purpose I/O ports Also serve as an LCD controller/driver segment output.
36	38	P50/PWM	F	General-purpose I/O port The output type can be switched between N-ch open-drain and CMOS. Also serves as an 8-bit PWM timer.
37, 38, 39	39, 40, 41	P51/TO2, P52/TO1, P53/EC	F	General-purpose I/O ports The output type can be switched between N-ch open-drain and CMOS. Also serves as an 8/16-bit timer/counter.

(Continued)

*1: FPT-80P-M05
*2: FPT-80P-M06
*3: MQP-80C-P01

(Continued)

Pin no.		Pin name	Circuit type	Function
SQFP*1,	QFP*2 MQFP*3			
40	42	P54/BUZ	F	General-purpose I/O port The output type can be switched beween N-ch open-drain and CMOS. Also serves as a buzzer output.
41, 42, 43	43, 44, 45	P55/SI, P56/SO, P57/SCK	F	General-purpose I/O ports The output type can be switched between N-ch open-drain and CMOS. Also serve as an 8-bit serial I/O.
74 to 59	76 to 61	SEG15 to SEG0	I	LCD controller/driver segment output pins
58, 57	60, 59	COM0, COM1	I	LCD controller/driver common output pins
56, 55	58, 57	COM2/P24, COM3/P23	H	LCD controller/driver common output pins These pins can be used as general-purpose I/O ports when they are not used as common output pins.
54 to 50	56 to 52	V3 to V0	—	LCD driving power supply pins
5	7	AV_{CC}	—	A/D converter and OP amp power supply pin
4	6	AVR	—	A/D converter reference voltage input pin
3	5	AV_{SS}	—	A/D converter and OP amp power supply (GND) pin
53	55	V_{CC}	—	Power supply pin
13, 49	15, 51	V_{SS}	—	Power supply (GND) pins

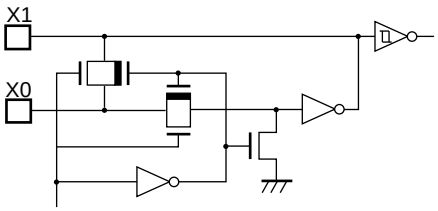
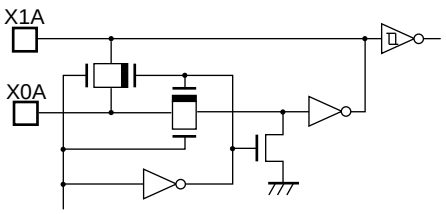
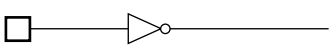
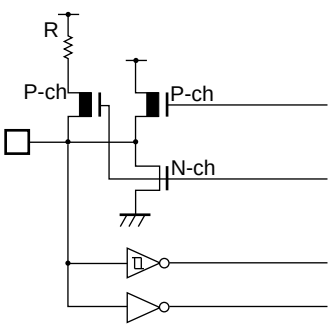
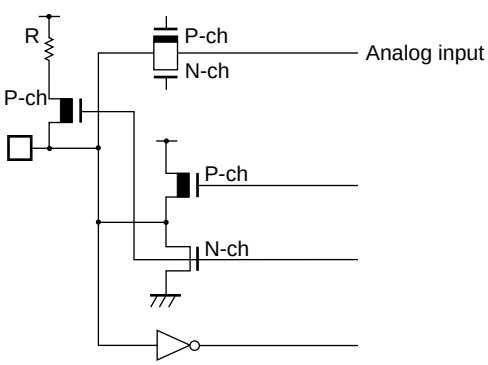
*1: FPT-80P-M05
*2: FPT-80P-M06
*3: MQP-80C-P01

MB89870 Series

- **External EPROM pins (MB89PV870 only)**

Pin no.	Pin name	I/O	Function
82	V_{PP}	O	“H” level output pin
83 84 85 86 87 88 89 90 91	A12 A7 A6 A5 A4 A3 A2 A1 A0	O	Address output pins
93 94 95	O1 O2 O3	I	Data input pins
96	V_{SS}	O	Power supply (GND) pin
98 99 100 101 102	O4 O5 O6 O7 O8	I	Data input pins
103	$\overline{CE}$	O	ROM chip enable pin Outputs “H” during standby.
104	A10	O	Address output pin
105	$\overline{OE}$	O	ROM output enable pin Outputs “L” at all times.
107 108 109	A11 A9 A8	O	Address output pins
110	A13	O	
111	A14	O	
112	V_{CC}	O	EPROM power supply pin
81 92 97 106	N.C.	—	Internally connected pins Be sure to leave them open.

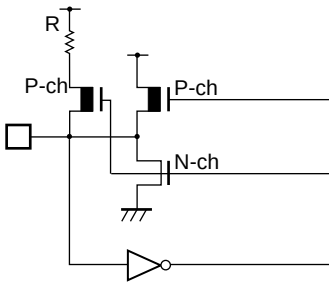
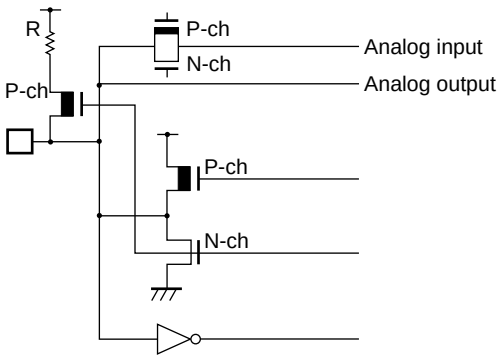
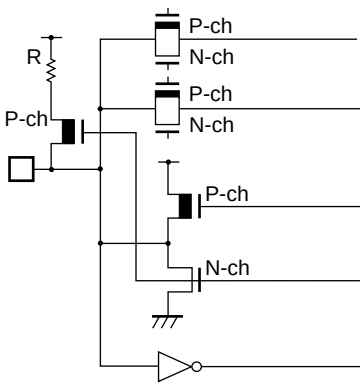
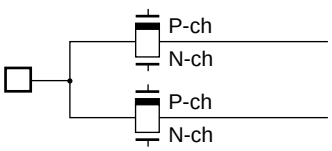
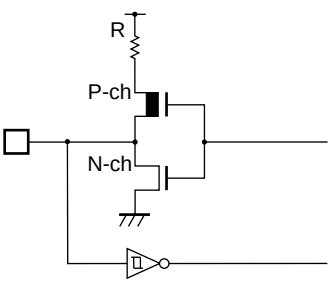
■ I/O CIRCUIT TYPE

Type	Circuit	Remarks
A		• External clock input selection versions for crystal or ceramic oscillation type (main clock) At an oscillation feedback resistor of approximately 1 MΩ/5.0 V
B		• Crystal or ceramic oscillation type (subclock) At an oscillation feedback resistor of approximately 4.5 MΩ/5.0 V
C		
D		• CMOS I/O (when selected as general-purpose ports) • Hysteresis input (when selected as an external interrupt input) • Pull-up resistor optional
E		• Analog input • CMOS I/O (when selected as general-purpose ports) • Pull-up resistor optional

(Continued)

MB89870 Series

(Continued)

Type	Circuit	Remarks
F		• CMOS I/O (when selected as general-purpose ports) • P50 to P57 are output only and can be switched between CMOS output and N-ch open-drain output. • Pull-up resistor optional
G		• Analog input • Analog output • CMOS I/O (when selected as general-purpose ports) • Pull-up resistor optional
H		• LCD controller/driver output • CMOS I/O (when selected as general-purpose ports) • Pull-up resistor optional
I		• LCD controller/driver output
J		• At an output pull-up resistor (P-ch) of approximately 50 kΩ/5.0 V • CMOS hysteresis input

■ HANDLING DEVICES

1. Preventing Latchup

Latchup may occur on CMOS ICs if voltage higher than V_{CC} or lower than V_{SS} is applied to input and output pins other than medium- to high-voltage pins or if higher than the voltage which shows on “1. Absolute Maximum Ratings” in section “■ Electrical Characteristics” is applied between V_{CC} and V_{SS}.

When latchup occurs, power supply current increases rapidly and might thermally damage elements. When using, take great care not to exceed the absolute maximum ratings.

Also, take care to prevent the analog power supply (AV_{CC} and AVR) and analog input from exceeding the digital power supply (V_{CC}) when the analog system power supply is turned on and off.

2. Treatment of Unused Input Pins

Leaving unused input pins open could cause malfunctions. They should be connected to a pull-up or pull-down resistor.

3. Treatment of Power Supply Pins on Microcontrollers with A/D and D/A Converters

Connect to be AV_{CC} = DAVC = V_{CC} and AV_{SS} = AVR = V_{SS} even if the A/D and D/A converters are not in use.

4. Treatment of N.C. Pins

Be sure to leave (internally connected) N.C. pins open.

5. Power Supply Voltage Fluctuations

Although V_{CC} power supply voltage is assured to operate within the rated range, a rapid fluctuation of the voltage could cause malfunctions, even if it occurs within the rated range. Stabilizing voltage supplied to the IC is therefore important. As stabilization guidelines, it is recommended to control power so that V_{CC} ripple fluctuations (P-P value) will be less than 10% of the standard V_{CC} value at the commercial frequency (50 to 60 Hz) and the transient fluctuation rate will be less than 0.1 V/ms at the time of a momentary fluctuation such as when power is switched.

6. Precautions when Using an External Clock

Even when an external clock is used, oscillation stabilization time is required for power-on reset (optional) and wake-up from stop mode.

■ PROGRAMMING TO THE EPROM ON THE MB89P875

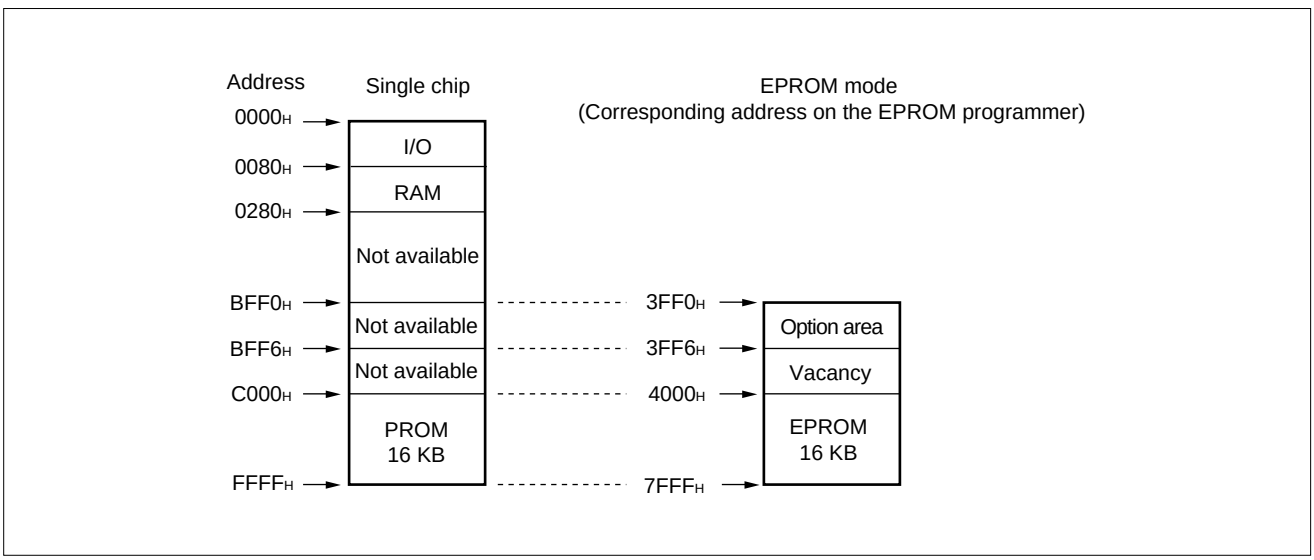
The MB89P875 is an OTPROM version of the MB89870 series.

1. Features

- 16-Kbyte PROM on chip
- Options can be set using the EPROM programmer.
- Equivalency to the MBM27C256A in EPROM mode (when programmed with the EPROM programmer)

2. Memory Space

Memory space in each mode such as 16-Kbyte PROM, option area is diagrammed below.



3. Programming to the EPROM

In EPROM mode, the MB89P875 functions equivalent to the MBM27C256A. This allows the PROM to be programmed with a general-purpose EPROM programmer (the electronic signature mode cannot be used) by using the dedicated socket adapater. When the operating ROM area for a single chip is 16 Kbytes (C000H to FFFFH) the PROM can be programmed as follows:

- **Programming procedure**

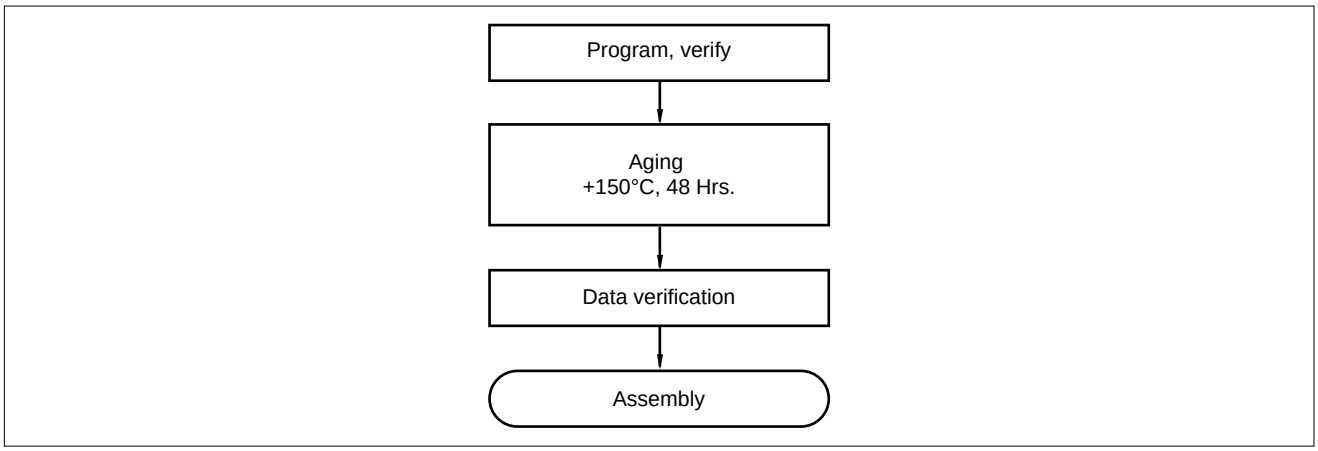
(1) Set the EPROM programmer to the MBM27C256A.

(2) Load program data into the EPROM programmer at 4000H to 7FFFH (note that addresses C000H to FFFFH while operating as a single chip assign to 4000H to 7FFFH in EPROM mode).
Load option data into addresses 3FF0H to 3FF6H of the EPROM programmer. (For information about each corresponding option, see “7. Setting OTPROM Options.”)

(3) Program to 3FF0H to 7FFFH with the EPROM programmer.

4. Recommended Screening Conditions

High-temperature aging is recommended as the pre-assembly screening procedure for a product with a blanked OTPROM microcomputer program.



5. Programming Yield

All bits cannot be programmed at Fujitsu shipping test to a blanked OTPROM microcomputer, due to its nature. For this reason, a programming yield of 100% cannot be assured at all times.

6. EPROM Programmer Socket Adapter

Package	Compatible socket adapter
FPT-80P-M06	ROM-80QF-28DP-8L3
FPT-80P-M05	ROM-80SQF-28DP-8L

Inquiry: Sun Hayato Co., Ltd.: TEL 81-3-3802-5760

7. Setting OTPROM Options

The programming procedure is the same as that for the PROM. Options can be set bu programming values at the addresses shown on the memory map. The relationship between bits and options is shown on the following bit map:

- **OTPROM option bit map**

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
$3FF0_H$	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Single/dual-clock system 1: Dual clock 0: Single clock	Reset pin output 1: Yes 0: No	Power-on reset 1: Yes 0: No	Oscillation stabilization time 00: $2^{18}/F_{CH}$ 10: $2^{13}/F_{CH}$ 01: $2^{17}/F_{CH}$ 11: 0	
$3FF1_H$	P07 Pull-up 1: No 0: Yes	P06 Pull-up 1: No 0: Yes	P05 Pull-up 1: No 0: Yes	P04 Pull-up 1: No 0: Yes	P03 Pull-up 1: No 0: Yes	P02 Pull-up 1: No 0: Yes	P01 Pull-up 1: No 0: Yes	P00 Pull-up 1: No 0: Yes
$3FF2_H$	Vacancy Readable and writable	Vacancy Readable and writable	P44 to P47 Pull-up 1: No 0: Yes	P40 to P43 Pull-up 1: No 0: Yes	P16, P17 Pull-up 1: No 0: Yes	P14, P15 Pull-up 1: No 0: Yes	P12, P13 Pull-up 1: No 0: Yes	P10, P11 Pull-up 1: No 0: Yes
$3FF3_H$	P37 Pull-up 1: No 0: Yes	P36 Pull-up 1: No 0: Yes	P35 Pull-up 1: No 0: Yes	P34 Pull-up 1: No 0: Yes	P33 Pull-up 1: No 0: Yes	P32 Pull-up 1: No 0: Yes	P31 Pull-up 1: No 0: Yes	P30 Pull-up 1: No 0: Yes
$3FF4_H$	P57 Pull-up 1: No 0: Yes	P56 Pull-up 1: No 0: Yes	P55 Pull-up 1: No 0: Yes	P54 Pull-up 1: No 0: Yes	P53 Pull-up 1: No 0: Yes	P52 Pull-up 1: No 0: Yes	P51 Pull-up 1: No 0: Yes	P50 Pull-up 1: No 0: Yes
$3FF5_H$	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	P24 Pull-up 1: No 0: Yes	P23 Pull-up 1: No 0: Yes	P22 Pull-up 1: No 0: Yes	P21 Pull-up 1: No 0: Yes	P20 Pull-up 1: No 0: Yes
$3FF6_H$	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Reserved bit Readable and writable

Notes:
- Set each bit to 1 to erase.
- Do not write 0 to the vacant bit.
  The read value of the vacant bit is 1, unless 0 is written to it.
- Always write 1 to the reserved bit.

■ PROGRAMMING TO THE EPROM WITH PIGGYBACK/EVALUATION DEVICE

1. EPROM for Use

MBM27C256A-20TV

2. Programming Socket Adapter

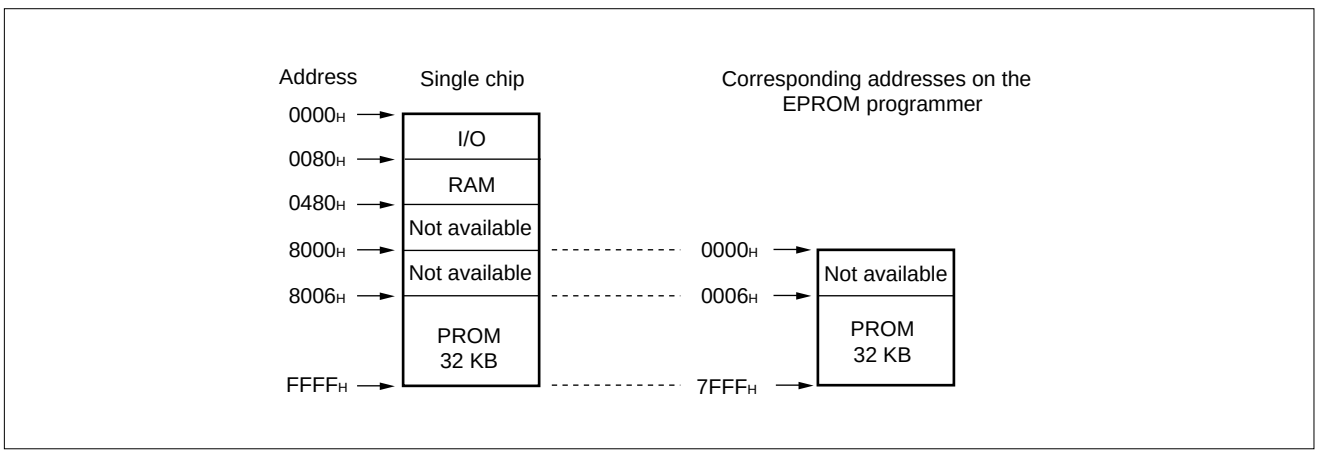
To program to the PROM using an EPROM programmer, use the socket adapter (manufacturer: Sun Hayato Co., Ltd.) listed below.

Package	Compatible socket part number
LCC-32 (Rectangle)	ROM-32LC-28DP-YG
LCC-32 (Square)	ROM-32LC-28DP-S

Inquiry: Sun Hayato Co., Ltd.: TEL 81-3-3802-5760

3. Memory Space

Memory space in 32-Kbyte PROM is diagrammed below.



4. Programming to the EPROM

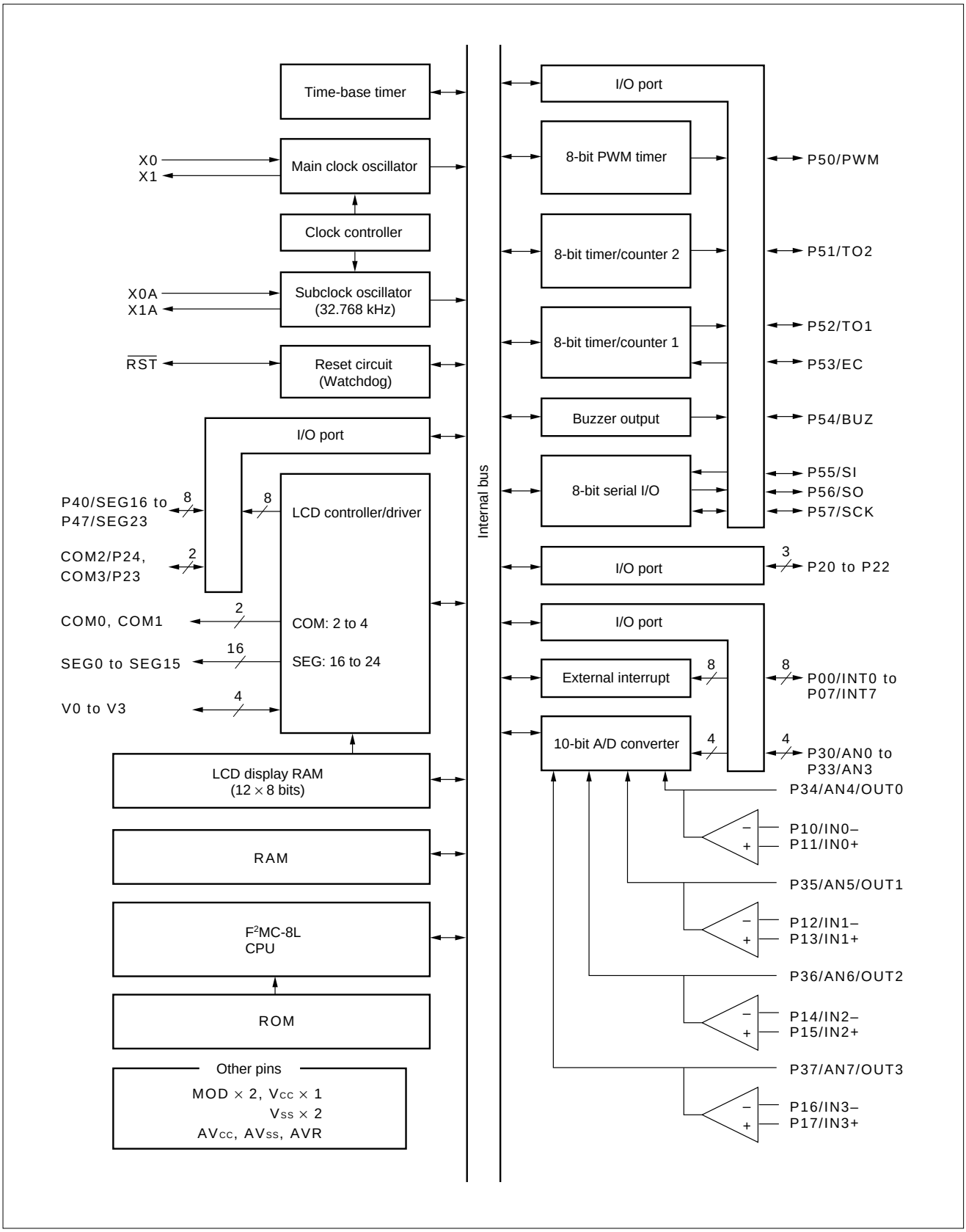
(1) Set the EPROM programmer to the MBM27C256A.

(2) Load program data into the EPROM programmer at 0006H to 7FFFH.

(3) Program to 0000H to 7FFFH with the EPROM programmer.

MB89870 Series

■ BLOCK DIAGRAM

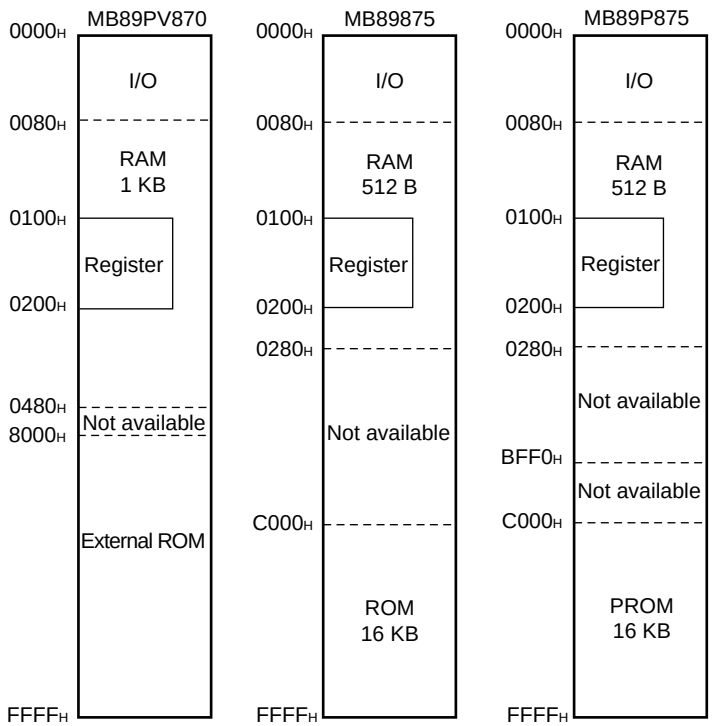


■ CPU CORE

1. Memory Space

The microcontrollers of the MB89870 series offer a memory space of 64 Kbytes for storing all of I/O, data, and program areas. The I/O area is located at the lowest address. The data area is provided immediately above the I/O area. The data area can be divided into register, stack, and direct areas according to the application. The program area is located at exactly the opposite end, that is, near the highest address. Provide the tables of interrupt reset vectors and vector call instructions toward the highest address within the program area. The memory space of the MB89870 series is structured as illustrated below.

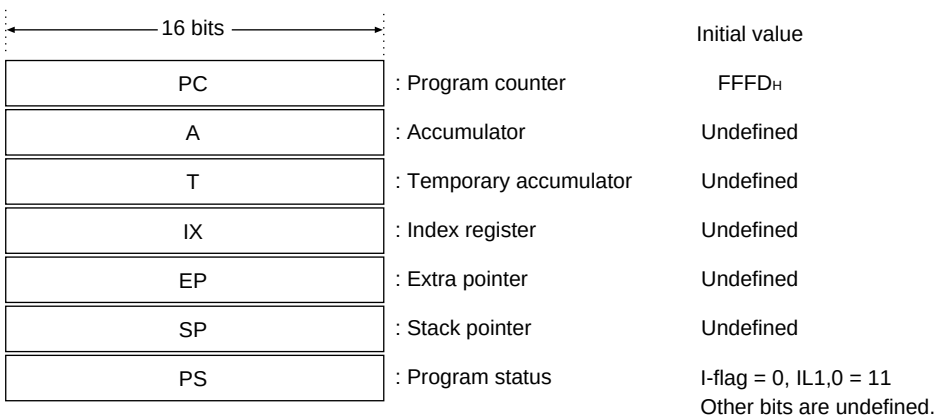
Memory Space



2. Registers

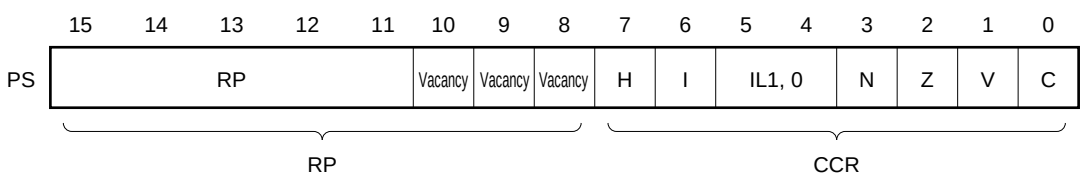
The F²MC-8L family has two types of registers; dedicated registers in the CPU and general-purpose registers in the memory. The following dedicated registers are provided:

Program counter (PC):	A 16-bit register for indicating instruction storage positions
Accumulator (A):	A 16-bit temporary register for storing arithmetic operations, etc. When the instruction is an 8-bit data processing instruction, the lower byte is used.
Temporary accumulator (T):	A 16-bit register which performs arithmetic operations with the accumulator When the instruction is an 8-bit data processing instruction, the lower byte is used.
Index register (IX):	A 16-bit register for index modification
Extra pointer (EP):	A 16-bit pointer for indicating a memory address
Stack pointer (SP):	A 16-bit register for indicating a stack area
Program status (PS):	A 16-bit register for storing a register pointer, a condition code



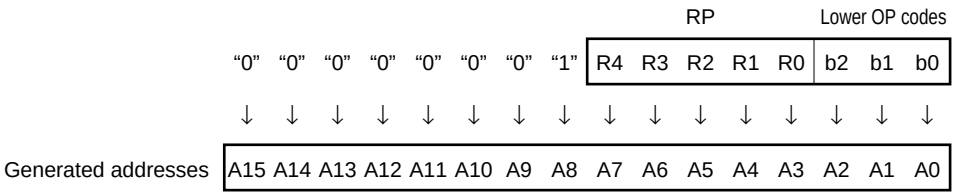
The PS can further be divided into higher 8 bits for use as a register bank pointer (RP) and the lower 8 bits for use as a condition code register (CCR). (See the diagram below.)

Structure of the Program Status Register



The RP indicates the address of the register bank currently in use. The relationship between the pointer contents and the actual address is based on the conversion rule illustrated below.

Rule for Conversion of Actual Addresses of the General-purpose Register Area



The CCR consists of bits indicating the results of arithmetic operations and the contents of transfer data and bits for control of CPU operations at the time of an interrupt.

H-flag: Set when a carry or a borrow from bit 3 to bit 4 occurs as a result of an arithmetic operation. Cleared otherwise. This flag is for decimal adjustment instructions.

I-flag: Interrupt is allowed when this flag is set to 1. Interrupt is prohibited when the flag is set to 0. Set to 0 when reset.

IL1, 0: Indicates the level of the interrupt currently allowed. Processes an interrupt only if its request level is higher than the value indicated by this bit.

IL1	IL0	Interrupt level	High-low
0	0	1	High ↕ Low = no interrupt
0	1		
1	0	2	
1	1	3	

N-flag: Set if the MSB is set to 1 as the result of an arithmetic operation. Cleared when the bit is set to 0.

Z-flag: Set when an arithmetic operation results in 0. Cleared otherwise.

V-flag: Set if the complement on 2 overflows as a result of an arithmetic operation. Reset if the overflow does not occur.

C-flag: Set when a carry or a borrow from bit 7 occurs as a result of an arithmetic operation. Cleared otherwise. Set to the shift-out value in the case of a shift instruction.

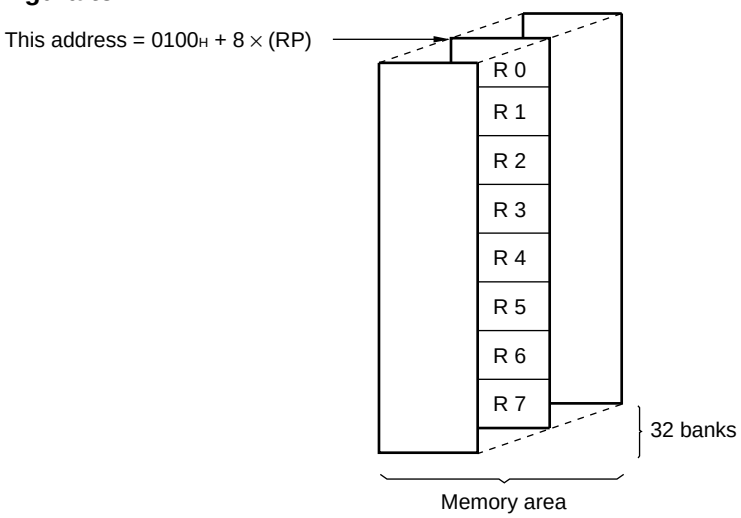
The following general-purpose registers are provided:

General-purpose registers: An 8-bit register for storing data

The general-purpose registers are 8 bits and located in the register banks of the memory. One bank contains eight registers and up to a total of 32 banks can be used on the MB89875 (RAM 512 × 8 bits). The bank currently in use is indicated by the register bank pointer (RP).

Note: The number of register banks that can be used varies with the RAM size.

Register Bank Configuraiton



■ I/O MAP

Address	Read/write	Register name	Register description	Bit name							
				Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
00H	R/W	PDR0	Port 0 data register	PD07	PD06	PD05	PD04	PD03	PD02	PD01	PD00
01H	W	DDR0	Port 0 data direction register	DD07	DD06	DD05	DD04	DD03	DD02	DD01	DD00
02H	R/W	PDR1	Port 1 data register	PD17	PD16	PD15	PD14	PD13	PD12	PD11	PD10
03H	W	DDR1	Port 1 data direction register	DD17	DD16	DD15	DD14	DD13	DD12	DD11	DD10
04H	R/W	PDR2	Port 2 data register	—	—	—	PD24	PD23	PD22	PD21	PD20
05H	R/W	DDR2	Port 2 data direction register	—	—	—	DD24	DD23	DD22	DD21	DD20
06H	Vacancy										
07H	R/W	SCC	System clock control register	SCM	—	—	WT1	WT0	SCS	CS1	CS0
08H	R/W	SMC	System mode control register	STP	SLP	SPL	RST	TMD	—	—	—
09H	R/W	WDTE	Watchdog timer control register	CS	—	—	—	WTE3	WTE2	WTE1	WTE0
0AH	R/W	TBCR	Time-base timer control register	TBIF	TBIE	—	—	—	TBC1	TBC0	TBR
0BH	R/W	WCR	Watch prescaler control register	WIF	WIE	WC1	WC0	—	WS1	WS0	WCLR
0CH	R/W	PDR3	Port 3 data register	PD37	PD36	PD35	PD34	PD33	PD32	PD31	PD30
0DH	R/W	DDR3	Port 3 data direction register	DD37	DD36	DD35	DD34	DD33	DD32	DD31	DD30
0EH	R/W	PDR4	Port 4 data register	PD47	PD46	PD45	PD44	PD43	PD42	PD41	PD40
0FH	R/W	DDR4	Port 4 data direction register	DD47	DD46	DD45	DD44	DD43	DD42	DD41	DD40
10H	Vacancy										
11H	Vacancy										
12H	Vacancy										
13H	Vacancy										
14H	Vacancy										
15H	Vacancy										
16H	R/W	PDR5	Port 5 data register	PD57	PD56	PD55	PD54	PD53	PD52	PD51	PD50
17H	R/W	DDR5	Port 5 data direction register	DD57	DD56	DD55	DD54	DD53	DD52	DD51	DD50
18H	Vacancy										
19H	Vacancy										
1AH	R/W	CHG5	Port 5 switching register	CHG1	—	—	—	CHG0	—	—	—
1BH	Vacancy										
1CH	Vacancy										

(Continued)

(Continued)

Address	Read/write	Register name	Register description	Bit name							
				Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
1D$_H$	W	ICR3	Port 3 input control register	PE37	PE36	PE35	PE34	PE33	PE32	PE31	PE30
1E$_H$	R/W	CNTR	PWM control register	P/TX	OE	P1	P0	TPE	TIR	OE1	TIE
1F$_H$	W	COMP	PWM compare register	CMP7	CMP6	CMP5	CMP4	CMP3	CMP2	CMP1	CMP0
20$_H$	Vacancy										
21$_H$	Vacancy										
22$_H$	Vacancy										
23$_H$	Vacancy										
24$_H$	R/W	T2CR	Timer 2 control register	T2IF	T2IE	TO21	TO20	TC21	TC20	STP2	STR2
25$_H$	R/W	T1CR	Timer 1 control register	T1IF	T1IE	TO11	TO10	TC11	TC10	STP1	STR1
26$_H$	R/W	T2DR	Timer 2 data register	T2D7	T2D6	T2D5	T2D4	T2D3	T2D2	T2D1	T2D0
27$_H$	R/W	T1DR	Timer 1 data register	T1D7	T1D6	T1D5	T1D4	T1D3	T1D2	T1D1	T1D0
28$_H$	R/W	SMR	Serial mode register	SIOF	SIOE	SCKE	SOE	CKS1	CKS0	BDS	SST
29$_H$	R/W	SDR	Serial data register	SDR7	SDR6	SDR5	SDR4	SDR3	SDR2	SDR1	SDR0
2A$_H$	Vacancy										
2B$_H$	Vacancy										
2C$_H$	R/W	OPC	OP amp control register	PD7	PD6	AD5	PD4	—	—	—	—
2D$_H$	R/W	ADC1	A/D conveter control register 1	ANS3	ANS2	ANS1	ANS0	ADI	ADMV	SIFM	AD
2E$_H$	R/W	ADC2	A/D converter control register 2	—	—	—	—	ADIE	ADMD	—	TEST
2F$_H$	R/W	ADCH	A/D converter data register	—	—	—	—	—	—	ADC9	ADC8
30$_H$	R/W	ADCL	A/D converter data register	ADC7	ADC6	ADC5	ADC4	ADC3	ADC2	ADC1	ADC0
31$_H$	R/W	EIE1	External interruput 1 enable register	EI71	EI70	EI61	IE60	EI51	EI50	EI41	EI40
32$_H$	R/W	EIF1	External interrupt 1 flag register	IF7	IF6	IF5	IF4	IE7	IE6	IE5	IE4
33$_H$	R/W	EIE2	External interrupt 2 enable register	EI3	IF3	—	—	IE3	IE2	IE1	IE0
34$_H$ to 5F$_H$	Vacancy										
60$_H$ to 6B$_H$	R/W	VRAM	Display data RAM	Display data							
6C$_H$ to 6F$_H$	Vacancy										

(Continued)

(Continued)

Address	Read/write	Register name	Register description	Bit name							
				Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
70H	R/W	LCR1	LCD controller/driver control register 1	CSS	LCEN	VSEL	BK	MS1	MS0	FP1	FP0
71H	R/W	LCR2	LCD controller/driver control register 2	COM1	COM0	SEG5	SEG4	SEG3	SEG2	SEG1	SEG0
72H to 7BH	Vacancy										
7CH	W	ILR1	Interrupt level setting register 1	L31	L30	L21	L20	L11	L10	L01	L00
7DH	W	ILR2	Interrupt level setting register 2	L71	L70	L61	L60	L51	L50	L41	L40
7EH	W	ILR3	Interrupt level setting register 3	LB1	LB0	LA1	LA0	L91	L90	L81	L80
7FH	Vacancy										

Note: Do not use vacancies.

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

(AV_{SS} = V_{SS} = 0.0 V)

Parameter	Symbol	Value		Unit	Remarks
		Min.	Max.		
Power supply voltage	V_{CC} AV_{CC}	V_{SS} – 0.3	V_{SS} + 7.0	V	*
A/D converter reference input voltage	AVR	V_{SS} – 0.3	V_{SS} + 7.0	V	
LCD power supply voltage	V0 to V3	V_{SS} – 0.3	V_{SS} + 7.0	V	V0 to V3 must not exceed V_{CC}.
Input voltage	V_I	V_{SS} – 0.3	V_{CC} + 0.3	V	
Output voltage	V_O	V_{SS} – 0.3	V_{CC} + 0.3	V	
“L” level maximum output current	I_{OL}	—	20	mA	
“L” level average output current	I_{OLAV}	—	4	mA	Average value (operating current × operating rate)
“L” level total maximum output current	$\sum I_{OL}$	—	100	mA	
“L” level total average output current	$\sum I_{OLAV}$	—	40	mA	Average value (operating current × operating rate)
“H” level maximum output current	I_{OH}	—	–20	mA	
“H” level average output current	I_{OHAV}	—	–4	mA	Average value (operating current × operating rate)
“H” level total maximum output current	$\sum I_{OH}$	—	–50	mA	
“H” level total average output current	$\sum I_{OHAV}$	—	–20	mA	Average value (operating current × operating rate)
Power consumption	P_D	—	300	mW	
Operating temperature	T_A	–40	+85	°C	
Storage temperature	Tstg	–55	+150	°C	

* : Use AV_{CC} and V_{CC} set at the same voltage.
Take care so that AVR does not exceed AV_{CC} + 0.3 V and AV_{CC} does not exceed V_{CC}, such as when power is turned on.

Precautions: Permanent device damage may occur if the above “Absolute Maximum Ratings” are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2. Recommended Operating Conditions

(AV_{SS} = V_{SS} = 0.0 V)

Parameter	Symbol	Value		Unit	Remarks
		Min.	Max.		
Power supply voltage	V_{CC} AV_{CC}	2.2*	6.0*	V	Normal operation assurance range* MB89875
		2.7	6.0	V	Normal operation assurance range MB89PV870/P875
		1.5	6.0	V	Retains the RAM state in stop mode
A/D converter reference input voltage	AVR	0.0	AV_{CC}	V	
LCD power supply voltage	V0 to V3	V_{SS}	V_{CC}	V	LCD power supply range (The optimum value is dependent on the LCD element in use.)
Operating temperature	T_A	–40	+85	°C	

* : These values vary with the operating frequency, instruction cycle, and analog assurance range. See Figure 1 and "5. A/D Converter Electrical Characteristics."

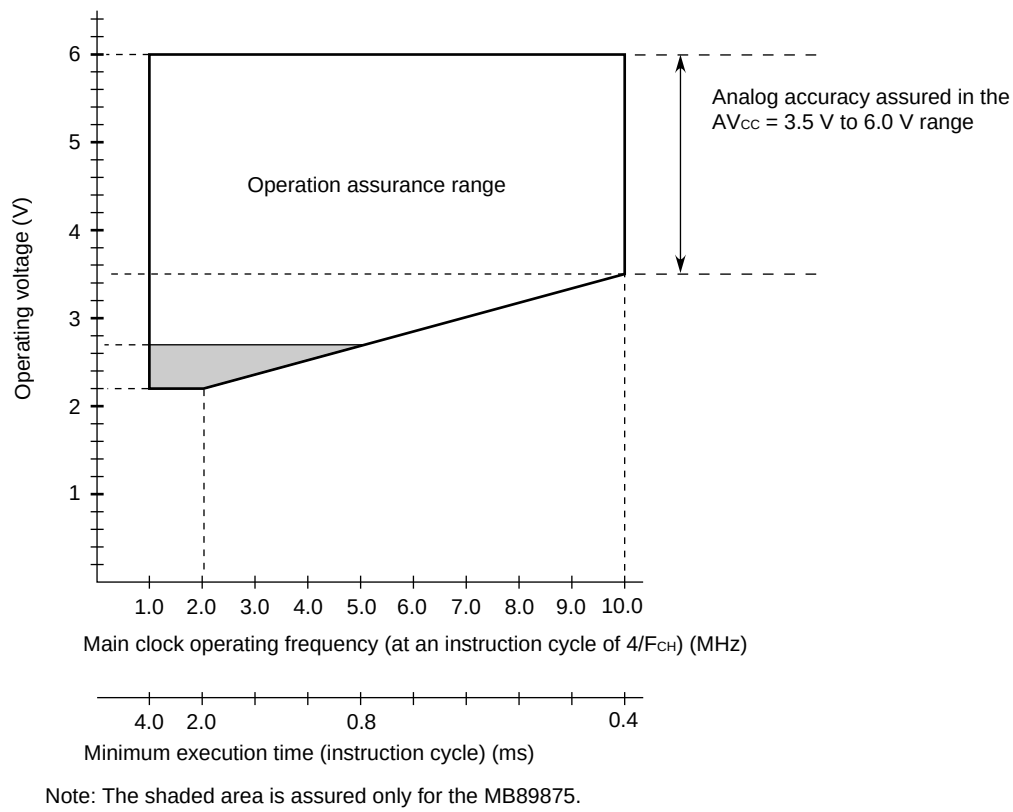


Figure 1 Operating Voltage vs. Main Clock Operating Frequency

Figure 1 indicates the operating frequency of the external oscillator at an instruction cycle of 4/F_{CH}.
Since the operating voltage range is dependent on the instruction cycle, see minimum execution time if the operating speed is switched using a gear.

3. DC Characteristics

(AV_{CC} = V_{CC} = 5.0 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
"H" level input voltage	V_{IH}	P20 to P24, P30 to P37, P40 to P47, P50 to P52, P54, P56	—	0.7 V_{CC}	—	V_{CC} + 0.3	V	
	V_{IHS}	P00 to P07, P10 to P17, MOD0, MOD1, $\overline{RST}$, P53, P55, P57	—	0.8 V_{CC}	—	V_{CC} + 0.3	V	
"L" level input voltage	V_{IL}	P20 to P24, P30 to P37, P40 to P47, P50 to P52, P54, P56	—	V_{SS} – 0.3	—	0.3 V_{CC}	V	
	V_{ILS}	P00 to P07, P10 to P17, MOD0, MOD1, $\overline{RST}$, P53, P55, P57	—	V_{SS} – 0.3	—	0.2 V_{CC}	V	
Open-drain output pin application voltage	V_D	P50 to P57	—	V_{SS} – 0.3	—	V_{CC} – 0.3	V	N-ch open-drain
"H" level output voltage	V_{OH}	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40 to P47, P50 to P57	I_{OH} = –2.0 mA	4.0	—	—	V	
"L" level output voltage	V_{OL}	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40 to P47, P50 to P57	I_{OL} = 4.0 mA	—	—	0.4	V	
Input leakage current (Hi-Z output leakage current)	I_{LI}	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40 to P47, P50 to P57 MOD0, MOD1, $\overline{RST}$	0.0 V < V_I < V_{CC}	—	—	±5	µA	With pull-up resistor
Pull-up resistance	R_{PULL}	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40 to P47, P50 to P57	V_I = 0.0 V	25	50	100	kΩ	With pull-up resistor

(Continued)

(AV_{CC} = V_{CC} = 5.0 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
Power supply current*1	I_{CC1}	V_{CC}	F_{CH} = 10 MHz, V_{CC} = 5.0 V, t_{inst}*2 = 0.4 µs	—	12	20	mA	
	I_{CC2}		F_{CH} = 10 MHz, V_{CC} = 3.0 V, t_{inst}*2 = 0.4 µs	—	1.0	2	mA	MB89875/ PV870
				—	1.5	2.5	mA	MB89P875
	I_{CCS1}		Sleep mode: F_{CH} = 10 MHz, V_{CC} = 5.0 V, t_{inst}*2 = 0.4 µs	—	3	7	mA	
	I_{CCS2}		Sleep mode: F_{CH} = 10 MHz, V_{CC} = 3.0 V, t_{inst}*2 = 6.4 µs	—	0.5	1.5	mA	
	I_{CCL}		F_{CL} = 32.768 kHz, V_{CC} = 3.0 V, Subclock mode	—	50	100	µA	MB89875/ PV870
				—	500	700	µA	MB89P875
	I_{CCLS}		F_{CL} = 32.768 kHz, V_{CC} = 3.0 V, Subclock sleep mode	—	15	50	µA	
	I_{CCT}		F_{CL} = 32.768 kHz, V_{CC} = 3.0 V • Watch mode • Main clock stop mode at dual-clock system	—	3	15	µA	
	I_{CCH}		T_A = +25°C • Subclock stop mode • Main clock stop mode at single-clock system	—	—	1	µA	
	I_A	AV_{CC}	F_{CH} = 10 MHz, when A/D conversion is activated	—	1.5	3	mA	
	I_{AH}		F_{CH} = 10 MHz, T_A = +25°C, when A/D conversion is stopped	—	—	1	µA	

(Continued)

(Continued)

(AV_{CC} = V_{CC} = 5.0 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
LCD divided resistance	R_{LCD}	—	Between V_{CC} and V0 at V_{CC} = 5.0 V	300	500	750	kΩ	
COM0 to 3 output impedance	R_{VCOM}	COM0 to 3	V1 to V3 = 5.0 V	—	—	2.5	kΩ	
SEG0 to 24 output impedance	R_{VSEG}	SEG0 to 24		—	—	15	kΩ	
LCD controller/driver leakage current	I_{LCDL}	V0 to V3, COM0 to 3 SEG0 to SEG24	—	—	—	±1	µA	
Input capacitance	C_{IN}	Other than AV_{CC}, AV_{SS}, V_{CC}, and V_{SS}	f = 1 MHz	—	10	—	pF	

*1: The power supply current is measured at the external clock.

*2: For information on t_{inst}, see “(4) Instruction Cycle” in “4. AC Characteristics.”

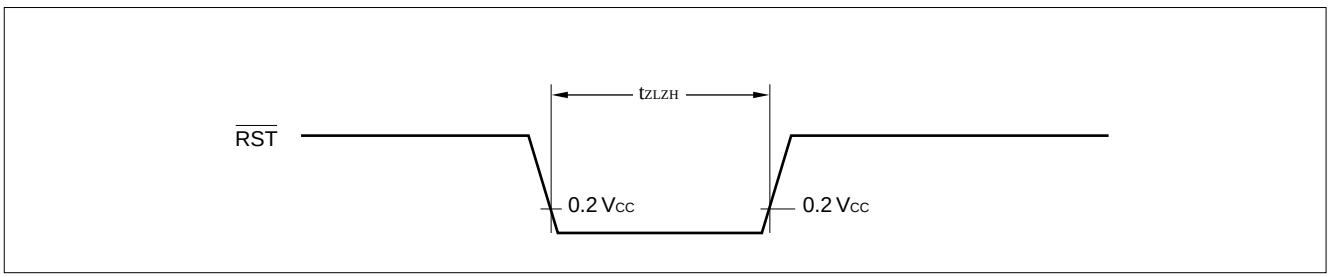
Note: For pins which serve as the LCD and ports (P23, P24 and P40 to P47), see the port parameter when these pins are used as ports and the LCD parameter when they are used as LCD pins.

4. AC Characteristics

(1) Reset Timing

(V_{CC} = +5.0 V ±10%, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min.	Max.		
$\overline{RST}$ "L" pulse width	t_{ZLZH}	—	48 t_{HCYL}	—	ns	

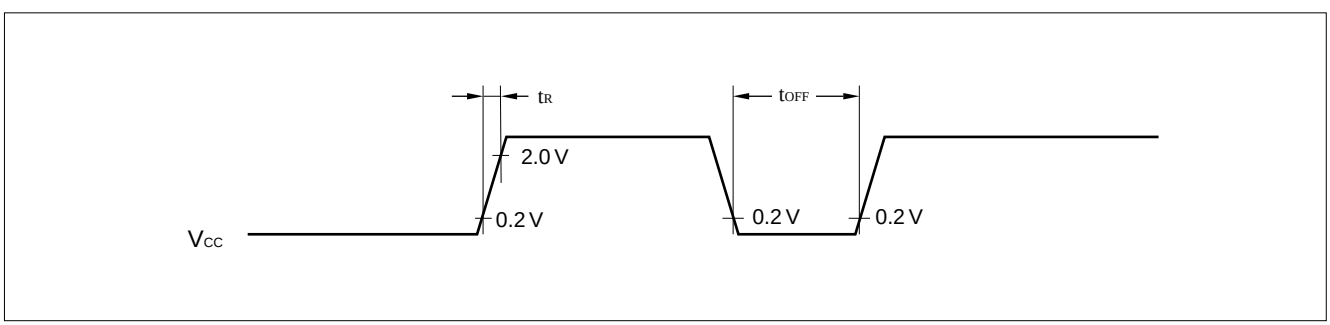


(2) Power-on Reset

(AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min.	Max.		
Power supply rising time	t_R	—	—	50	ms	Power-on reset function only
Power supply cut-off time	t_{OFF}		1	—	ms	Due to repeated operations

Note: Make sure that power supply rises within the selected oscillation stabilization time.
If power supply voltage needs to be varied in the course of operation, a smooth voltage rise is recommended.

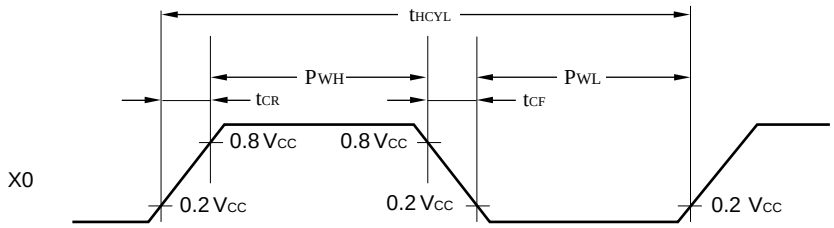


(3) Clock Timing

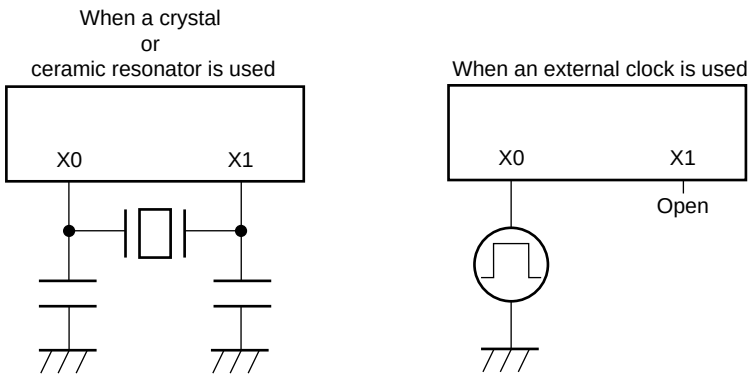
(AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
Clock frequency	F_{CH}	X0, X1	—	1	—	10	MHz	
	F_{CL}	X0A, X1A		—	32.768	—	kHz	
Clock cycle time	t_{HCYL}	X0, X1		100	—	1000	ns	
	t_{LCYL}	X0A, X1A		—	30.5	—	µs	
Input clock pulse width	P_{WH} P_{WL}	X0		20	—	—	ns	External clock
Input clock rising/falling time	t_{CR} t_{CF}	X0		—	—	10	ns	External clock

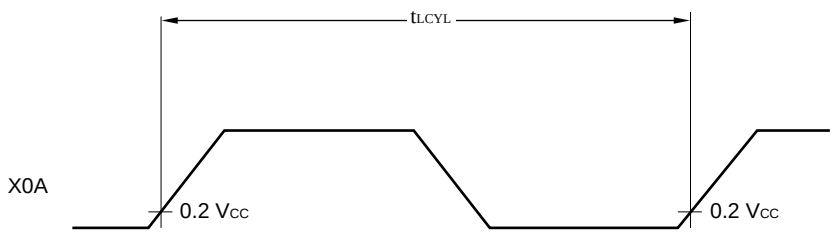
X0 and X1 Timing and Conditions



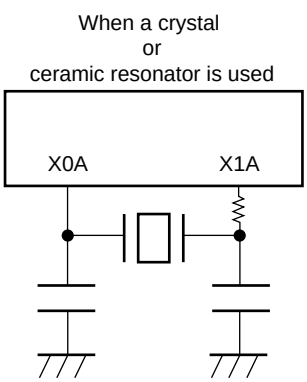
Main Clock Conditions



X0A and X1A Timing and Conditions



Subclock Conditions



(4) Instruction Cycle

Parameter	Symbol	Value (typical)	Unit	Remarks
Instruction cycle (minimum execution time)	t_{inst}	$4/F_{CH}$, $8/F_{CH}$, $16/F_{CH}$, $64/F_{CH}$	µs	($4/F_{CH}$) t_{inst} = 0.4 µs when operating at F_{CH} = 10 MHz
		$2/F_{CL}$	µs	t_{inst} = 61.036 µs when operating at F_{CL} = 32.768 kHz

Note: When operating at 10 MHz, the cycle varies with the set execution time.

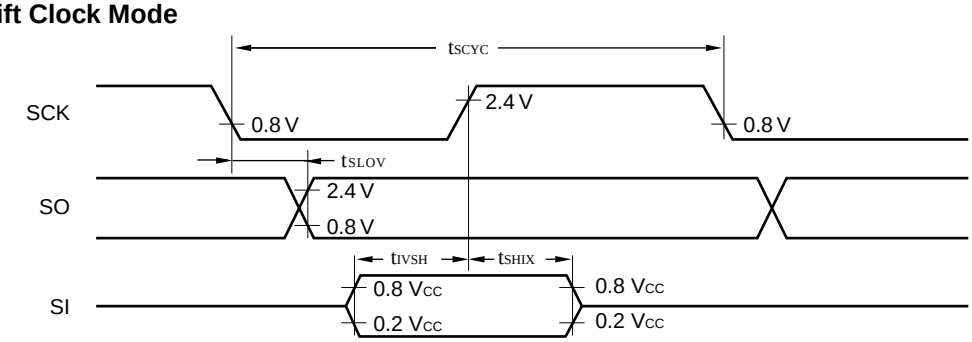
(5) Serial I/O Timing

(V_{CC} = +5.0 V±10%, AV_{SS} = V_{SS}= 0.0 V, T_A = –40°C to +85°C)

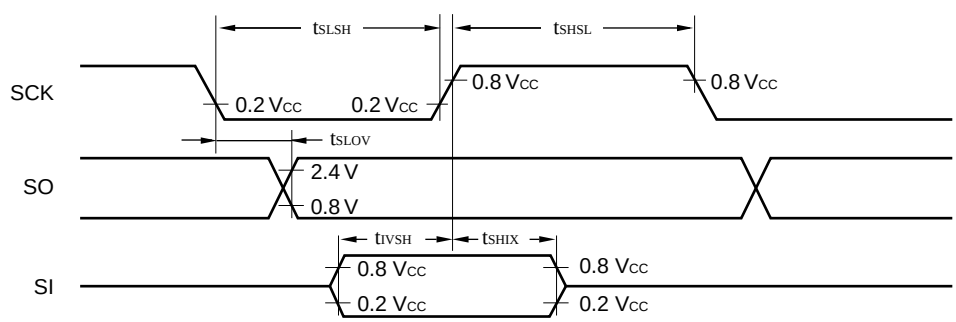
Parameter	Symbol	Pin	Condition	Value		Unit	Remarks
				Min.	Max.		
Serial clock cycle time	t_{SCYC}	SCK	Internal shift clock mode	2 t_{inst}*	—	µs	
SCK ↓ → SO time	t_{SLOV}	SCK, SO		–200	200	ns	
Valid SI → SCK ↑	t_{IVSH}	SI, SCK		1/2 t_{inst}*	—	µs	
SCK ↑ → valid SI hold time	t_{SHIX}	SCK, SI		1/2 t_{inst}*	—	µs	
Serial clock “H” pulse width	t_{SHSL}	SCK	External shift clock mode	1 t_{inst}*	—	µs	
Serial clock “L” pulse width	t_{SLSH}			1 t_{inst}*	—	µs	
SCK ↓ → SO time	t_{SLOV}	SCK, SO		0	200	ns	
Valid SI → SCK ↑	t_{IVSH}	SI, SCK		1/2 t_{inst}*	—	µs	
SCK ↑ → valid SI hold time	t_{SHIX}	SCK, SI		1/2 t_{inst}*	—	µs	

* : For information on t_{inst}, see “(4) Instruction Cycle.”

Internal Shift Clock Mode



External Shift Clock Mode

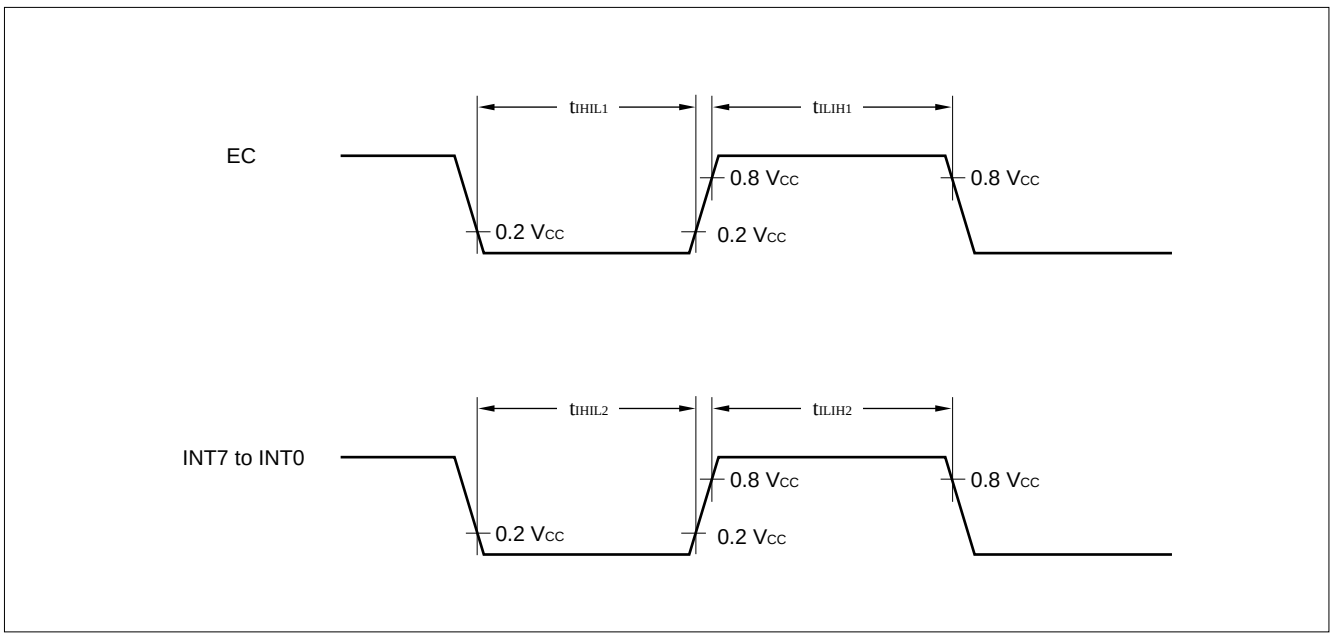


(6) Peripheral Input Timing

(V_{CC} = +5.0 V ±10%, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin	Value		Unit	Remarks
			Min.	Max.		
Peripheral input “H” pulse width 1	t_{ILIH1}	EC	1 t_{inst}*	—	µs	
Peripheral input “L” pulse width 1	t_{IHIL1}		1 t_{inst}*	—	µs	
Peripheral input “H” pulse width 2	t_{ILIH2}	INT7 to INT0	2 t_{inst}*	—	µs	
Peripheral input “L” pulse width 2	t_{IHIL2}		2 t_{inst}*	—	µs	

* : For information on t_{inst}, see “(4) Instruction Cycle.”



5. A/D Converter Electrical Characteristics

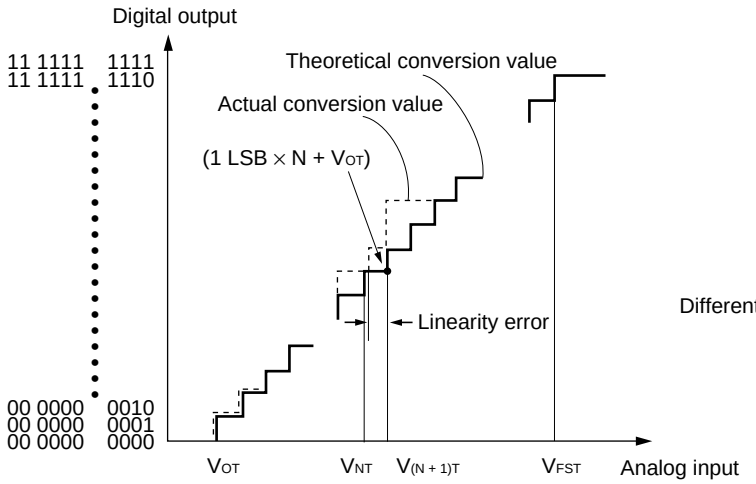
(AV_{CC} = V_{CC} = +3.5 V to +6.0 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
Resolution	—	—	—	—	—	10	bit	
Total error			AVR = AV_{CC}	—	—	±3.0	LSB	
Linearity error				—	—	±2.0	LSB	
Differential linearity error				—	—	±1.5	LSB	
Zero transition voltage	V_{OT}			AV_{SS} – 1.5 LSB	AV_{SS} + 0.5 LSB	AV_{SS} + 2.5 LSB	mV	
Full-scale transition voltage	V_{FST}			AVR – 3.5 LSB	AVR – 1.5 LSB	AVR + 0.5 LSB	mV	
Interchannel disparity	—			—	—	4.0	LSB	
A/D mode conversion time			—	—	33 t_{inst}*	—	µs	
Sense mode conversion time				—	18 t_{inst}*	—	µs	
Analog port input current	I_{AIN}	AN0 to AN7		—	—	10	µA	
Analog input voltage	—			0.0	—	AVR	V	
Reference voltage	—	AVR		0.0	—	AV_{CC}	V	
Reference voltage supply current	I_R		AVR = 5.0 V, when A/D conversion is activated	—	200	—	µA	
	I_{RH}		AVR = 5.0 V, when A/D conversion is stopped	—	—	1	µA	

* : For information on t_{inst}, see “(4) Instruction Cycle” in “4. AC Characteristics.”

(1) A/D Glossary

- Resolution
  Analog changes that are identifiable with the A/D converter
  When the number of bits is 10, analog voltage can be divided into 2^{10} = 1024.
- Linearity error (unit: LSB)
  The deviation of the straight line connecting the zero transition point (“00 0000 0000” ↔ “00 0000 0001”) with the full-scale transition point (“11 1111 1111” ↔ “11 1111 1110”) from actual conversion characteristics
- Differential linearity error (unit: LSB)
  The deviation of input voltage needed to change the output code by 1 LSB from the theoretical value
- Total error (unit: LSB)
  The difference between theoretical and actual conversion values



$$1\ \text{LSB} = \frac{\text{AVR}}{1024}$$

$$\text{Linearity error} = \frac{V_{NT} - (1\ \text{LSB} \times N + V_{OT})}{1\ \text{LSB}}$$

$$\text{Differential linearity error} = \frac{V_{(N+1)T} - V_{NT}}{1\ \text{LSB}} - 1$$

$$\text{Total error} = \frac{V_{NT} - (1\ \text{LSB} \times N + 1\ \text{LSB})}{1\ \text{LSB}}$$

(2) Precautions

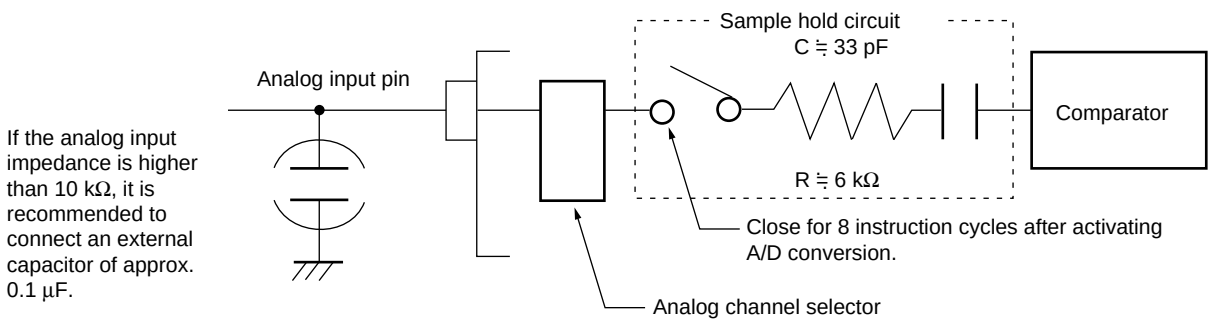
- **Input impedance of the analog input pins**

The A/D converter used for the MB89870 series contains a sample hold circuit as illustrated below to fetch analog input voltage into the sample hold capacitor for eight instruction cycles after activating A/D conversion.

For this reason, if the output impedance of the external circuit for the analog input is high, analog input voltage might not stabilize within the analog input sampling period. Therefore, it is recommended to keep the output impedance of the external circuit low (below 10 kΩ).

Note that if the impedance cannot be kept low, it is recommended to connect an external capacitor of about 0.1 µF for the analog input pin.

Analog Input Equivalent Circuit



- **Error**

The smaller the | AVR – AVSS |, the greater the error would become relatively.

6. OP Amp Electrical Characteristics

(1) AV_{CC} = 5.0 V

(AV_{CC} = V_{CC} = 4.5 V to 5.5 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
I/O voltage range	—	IN0± to IN3±	—	0.5 V_{CC} – 1.25	0.5 V_{CC}	0.5 V_{CC} + 1.25	V	
Minimum load resistance	—	—	—	100	—	—	kΩ	
Maximum load resistance	—	—	—	—	—	100	pF	
Offset voltage	—	—	—	–10	0	+10	mV	
Gain-bandwidth production	—	—	—	—	1.8	—	MHz	
DC gain	—	—	—	—	75	—	dB	
Slew rate	—	—	—	—	0.9	—	V/µs	

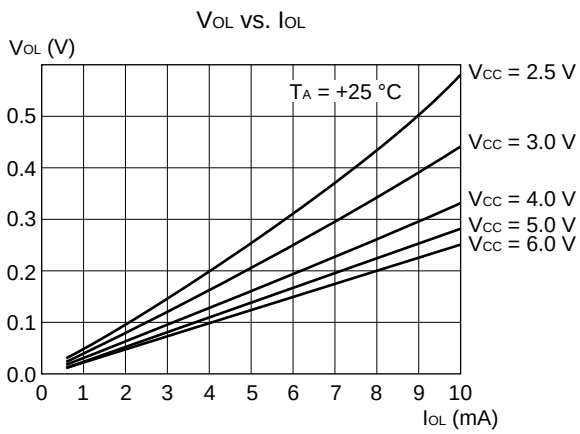
(2) AV_{CC} = 3.0 V

(AV_{CC} = V_{CC} = 2.7 V to 3.3 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

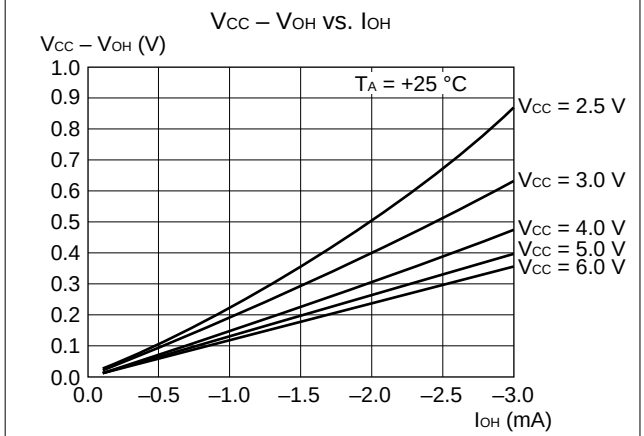
Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
I/O voltage range	—	IN0± to IN3±	—	0.5	0.5 V_{CC} – 0.35	V_{CC} – 1.20	V	
Minimum load resistance	—	—	—	250	—	—	kΩ	
Maximum load resistance	—	—	—	—	—	100	µA	
Offset voltage	—	—	—	–10	0	+10	mV	
Gain-bandwidth production	—	—	—	—	0.5	—	MHz	
DC gain	—	—	—	—	75	—	dB	
Slew rate	—	—	—	—	0.1	—	V/µs	

■ EXAMPLE CHARACTERISTICS

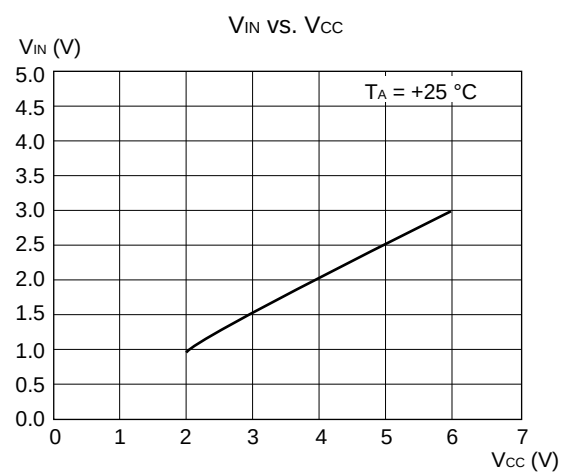
(1) “L” Level Output Voltage



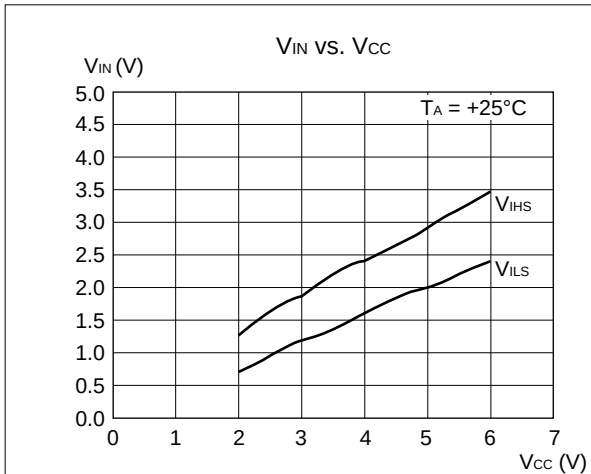
(2) “H” Level Output Voltage



(3) “H” Level Input Voltage/“L” Level Input Voltage (CMOS Input)



(4) “H” Level Input Voltage/“L” Level Input Voltage (Hysteresis Input)



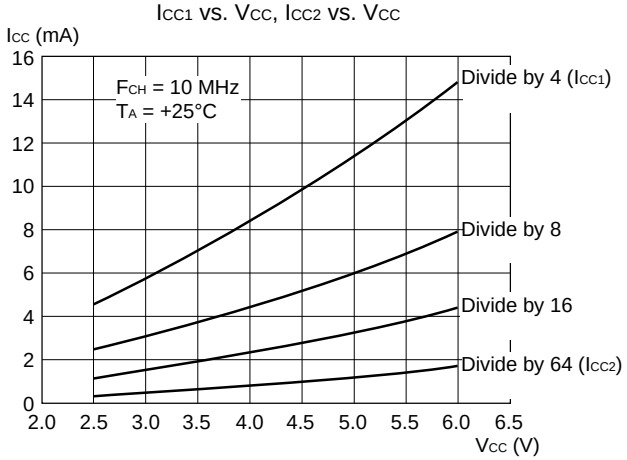
VIHS: Threshold when input voltage in hysteresis characteristics is set to “H” level

VILS: Threshold when input voltage in hysteresis characteristics is set to “L” level

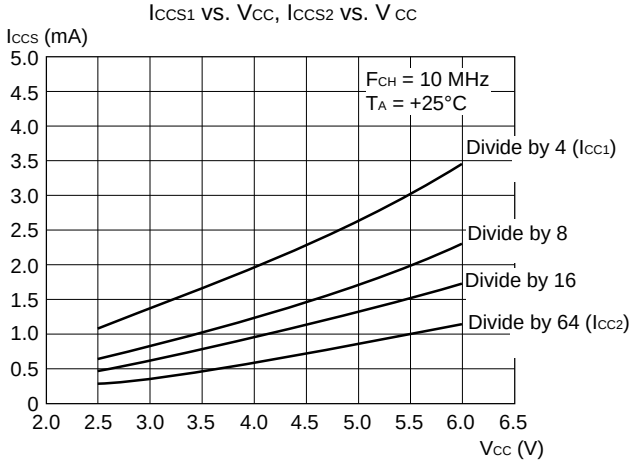
MB89870 Series

(5) Power Supply Current (External Clock)

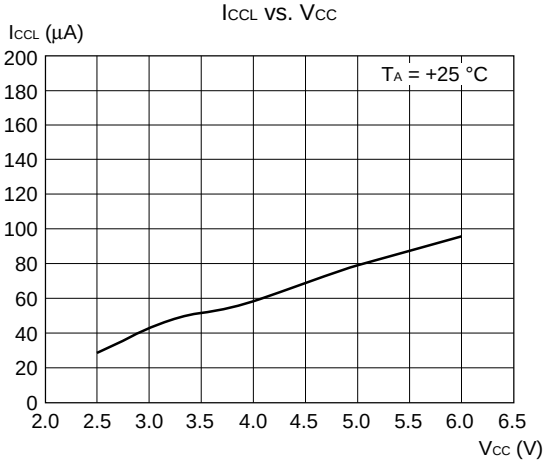
I_{CC1} vs. V_{CC}, I_{CC2} vs. V_{CC}



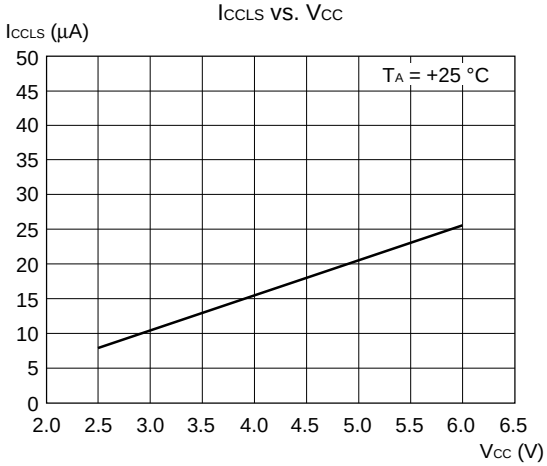
I_{CCS1} vs. V_{CC}, I_{CCS2} vs. V_{CC}



I_{CCL} vs. V_{CC}



I_{CCLS} vs. V_{CC}



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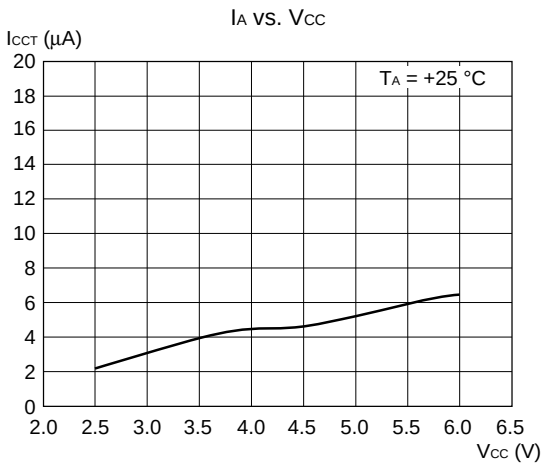
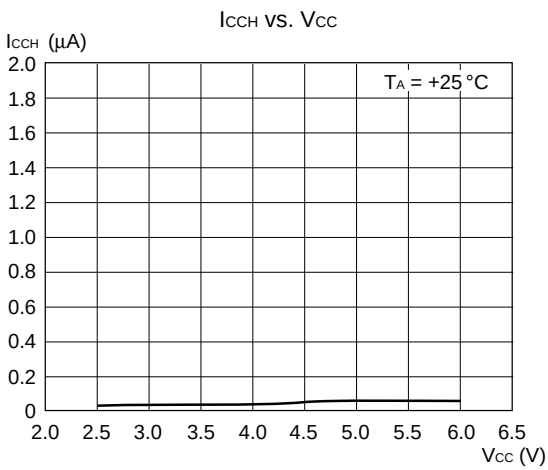
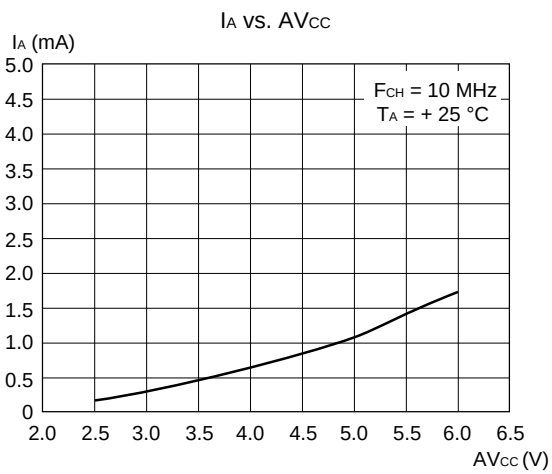
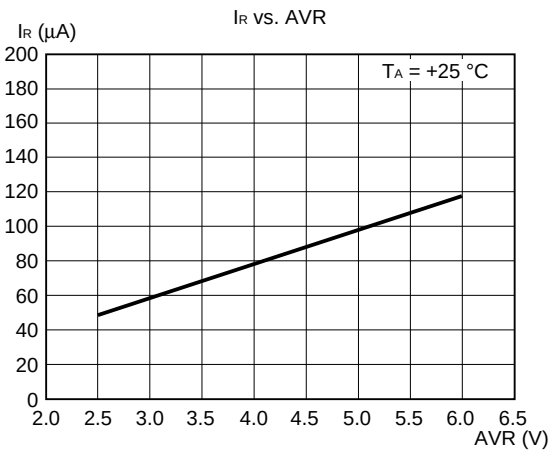
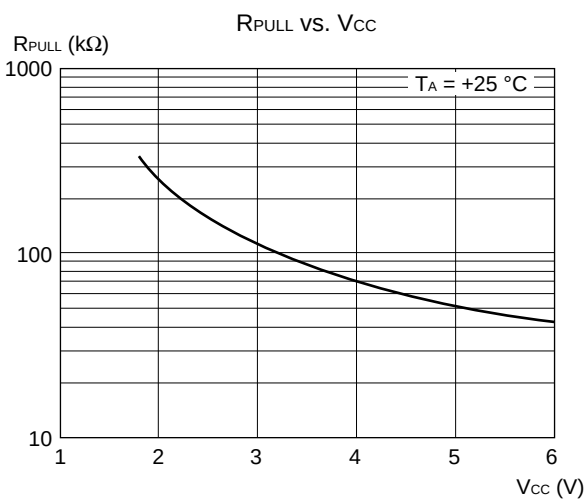








(6) Pull-up Resistance



■ INSTRUCTIONS

Execution instructions can be divided into the following four groups:

- Transfer
- Arithmetic operation
- Branch
- Others

Table 1 lists symbols used for notation of instructions.

Table 1 Instruction Symbols

Symbol	Meaning
dir	Direct address (8 bits)
off	Offset (8 bits)
ext	Extended address (16 bits)
#vct	Vector table number (3 bits)
#d8	Immediate data (8 bits)
#d16	Immediate data (16 bits)
dir: b	Bit direct address (8:3 bits)
rel	Branch relative address (8 bits)
@	Register indirect (Example: @A, @IX, @EP)
A	Accumulator A (Whether its length is 8 or 16 bits is determined by the instruction in use.)
AH	Upper 8 bits of accumulator A (8 bits)
AL	Lower 8 bits of accumulator A (8 bits)
T	Temporary accumulator T (Whether its length is 8 or 16 bits is determined by the instruction in use.)
TH	Upper 8 bits of temporary accumulator T (8 bits)
TL	Lower 8 bits of temporary accumulator T (8 bits)
IX	Index register IX (16 bits)

(Continued)

(Continued)

Symbol	Meaning
EP	Extra pointer EP (16 bits)
PC	Program counter PC (16 bits)
SP	Stack pointer SP (16 bits)
PS	Program status PS (16 bits)
dr	Accumulator A or index register IX (16 bits)
CCR	Condition code register CCR (8 bits)
RP	Register bank pointer RP (5 bits)
Ri	General-purpose register Ri (8 bits, i = 0 to 7)
×	Indicates that the very × is the immediate data. (Whether its length is 8 or 16 bits is determined by the instruction in use.)
(×)	Indicates that the contents of × is the target of accessing. (Whether its length is 8 or 16 bits is determined by the instruction in use.)
((×))	The address indicated by the contents of × is the target of accessing. (Whether its length is 8 or 16 bits is determined by the instruction in use.)

Columns indicate the following:

Mnemonic: Assembler notation of an instruction

~: Number of instructions

#: Number of bytes

Operation: Operation of an instruction

TL, TH, AH: A content change when each of the TL, TH, and AH instructions is executed. Symbols in the column indicate the following:

- "–" indicates no change.
- dH is the 8 upper bits of operation description data.
- AL and AH must become the contents of AL and AH immediately before the instruction is executed.
- 00 becomes 00.

N, Z, V, C: An instruction of which the corresponding flag will change. If + is written in this column, the relevant instruction will change its corresponding flag.

OP code: Code of an instruction. If an instruction is more than one code, it is written according to the following rule:

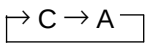
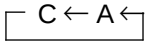
Example: 48 to 4F ← This indicates 48, 49, ... 4F.

Table 2 Transfer Instructions (48 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	N Z V C	OP code
MOV dir,A	3	2	(dir) ← (A)	–	–	–	– – – –	45
MOV @IX +off,A	4	2	((IX) +off) ← (A)	–	–	–	– – – –	46
MOV ext,A	4	3	(ext) ← (A)	–	–	–	– – – –	61
MOV @EP,A	3	1	((EP)) ← (A)	–	–	–	– – – –	47
MOV Ri,A	3	1	(Ri) ← (A)	–	–	–	– – – –	48 to 4F
MOV A,#d8	2	2	(A) ← d8	AL	–	–	+ + – –	04
MOV A,dir	3	2	(A) ← (dir)	AL	–	–	+ + – –	05
MOV A,@IX +off	4	2	(A) ← ((IX) +off)	AL	–	–	+ + – –	06
MOV A,ext	4	3	(A) ← (ext)	AL	–	–	+ + – –	60
MOV A,@A	3	1	(A) ← ((A))	AL	–	–	+ + – –	92
MOV A,@EP	3	1	(A) ← ((EP))	AL	–	–	+ + – –	07
MOV A,Ri	3	1	(A) ← (Ri)	AL	–	–	+ + – –	08 to 0F
MOV dir,#d8	4	3	(dir) ← d8	–	–	–	– – – –	85
MOV @IX +off,#d8	5	3	((IX) +off) ← d8	–	–	–	– – – –	86
MOV @EP,#d8	4	2	((EP)) ← d8	–	–	–	– – – –	87
MOV Ri,#d8	4	2	(Ri) ← d8	–	–	–	– – – –	88 to 8F
MOVW dir,A	4	2	(dir) ← (AH),(dir + 1) ← (AL)	–	–	–	– – – –	D5
MOVW @IX +off,A	5	2	((IX) +off) ← (AH), ((IX) +off + 1) ← (AL)	–	–	–	– – – –	D6
MOVW ext,A	5	3	(ext) ← (AH), (ext + 1) ← (AL)	–	–	–	– – – –	D4
MOVW @EP,A	4	1	((EP)) ← (AH),((EP) + 1) ← (AL)	–	–	–	– – – –	D7
MOVW EP,A	2	1	(EP) ← (A)	–	–	–	– – – –	E3
MOVW A,#d16	3	3	(A) ← d16	AL	AH	dH	+ + – –	E4
MOVW A,dir	4	2	(AH) ← (dir), (AL) ← (dir + 1)	AL	AH	dH	+ + – –	C5
MOVW A,@IX +off	5	2	(AH) ← ((IX) +off), (AL) ← ((IX) +off + 1)	AL	AH	dH	+ + – –	C6
MOVW A,ext	5	3	(AH) ← (ext), (AL) ← (ext + 1)	AL	AH	dH	+ + – –	C4
MOVW A,@A	4	1	(AH) ← ((A)), (AL) ← ((A)) + 1)	AL	AH	dH	+ + – –	93
MOVW A,@EP	4	1	(AH) ← ((EP)), (AL) ← ((EP) + 1)	AL	AH	dH	+ + – –	C7
MOVW A,EP	2	1	(A) ← (EP)	–	–	dH	– – – –	F3
MOVW EP,#d16	3	3	(EP) ← d16	–	–	–	– – – –	E7
MOVW IX,A	2	1	(IX) ← (A)	–	–	–	– – – –	E2
MOVW A,IX	2	1	(A) ← (IX)	–	–	dH	– – – –	F2
MOVW SP,A	2	1	(SP) ← (A)	–	–	–	– – – –	E1
MOVW A,SP	2	1	(A) ← (SP)	–	–	dH	– – – –	F1
MOV @A,T	3	1	((A)) ← (T)	–	–	–	– – – –	82
MOVW @A,T	4	1	((A)) ← (TH),((A) + 1) ← (TL)	–	–	–	– – – –	83
MOVW IX,#d16	3	3	(IX) ← d16	–	–	–	– – – –	E6
MOVW A,PS	2	1	(A) ← (PS)	–	–	dH	– – – –	70
MOVW PS,A	2	1	(PS) ← (A)	–	–	–	+ + + +	71
MOVW SP,#d16	3	3	(SP) ← d16	–	–	–	– – – –	E5
SWAP	2	1	(AH) ↔ (AL)	–	–	AL	– – – –	10
SETB dir: b	4	2	(dir): b ← 1	–	–	–	– – – –	A8 to AF
CLRB dir: b	4	2	(dir): b ← 0	–	–	–	– – – –	A0 to A7
XCH A,T	2	1	(AL) ↔ (TL)	AL	–	–	– – – –	42
XCHW A,T	3	1	(A) ↔ (T)	AL	AH	dH	– – – –	43
XCHW A,EP	3	1	(A) ↔ (EP)	–	–	dH	– – – –	F7
XCHW A,IX	3	1	(A) ↔ (IX)	–	–	dH	– – – –	F6
XCHW A,SP	3	1	(A) ↔ (SP)	–	–	dH	– – – –	F5
MOVW A,PC	2	1	(A) ← (PC)	–	–	dH	– – – –	F0

Notes:
- During byte transfer to A, T ← A is restricted to low bytes.
- Operands in more than one operand instruction must be stored in the order in which their mnemonics are written. (Reverse arrangement of F²MC-8 family)

Table 3 Arithmetic Operation Instructions (62 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	N Z V C	OP code
ADDC A,Ri	3	1	(A) ← (A) + (Ri) + C	–	–	–	+ + + +	28 to 2F
ADDC A,#d8	2	2	(A) ← (A) + d8 + C	–	–	–	+ + + +	24
ADDC A,dir	3	2	(A) ← (A) + (dir) + C	–	–	–	+ + + +	25
ADDC A,@IX +off	4	2	(A) ← (A) + ((IX) +off) + C	–	–	–	+ + + +	26
ADDC A,@EP	3	1	(A) ← (A) + ((EP)) + C	–	–	–	+ + + +	27
ADDCW A	3	1	(A) ← (A) + (T) + C	–	–	dH	+ + + +	23
ADDC A	2	1	(AL) ← (AL) + (TL) + C	–	–	–	+ + + +	22
SUBC A,Ri	3	1	(A) ← (A) – (Ri) – C	–	–	–	+ + + +	38 to 3F
SUBC A,#d8	2	2	(A) ← (A) – d8 – C	–	–	–	+ + + +	34
SUBC A,dir	3	2	(A) ← (A) – (dir) – C	–	–	–	+ + + +	35
SUBC A,@IX +off	4	2	(A) ← (A) – ((IX) +off) – C	–	–	–	+ + + +	36
SUBC A,@EP	3	1	(A) ← (A) – ((EP)) – C	–	–	–	+ + + +	37
SUBCW A	3	1	(A) ← (T) – (A) – C	–	–	dH	+ + + +	33
SUBC A	2	1	(AL) ← (TL) – (AL) – C	–	–	–	+ + + +	32
INC Ri	4	1	(Ri) ← (Ri) + 1	–	–	–	+ + + –	C8 to CF
INCW EP	3	1	(EP) ← (EP) + 1	–	–	–	– – – –	C3
INCW IX	3	1	(IX) ← (IX) + 1	–	–	–	– – – –	C2
INCW A	3	1	(A) ← (A) + 1	–	–	dH	+ + – –	C0
DEC Ri	4	1	(Ri) ← (Ri) – 1	–	–	–	+ + + –	D8 toDF
DECW EP	3	1	(EP) ← (EP) – 1	–	–	–	– – – –	D3
DECW IX	3	1	(IX) ← (IX) – 1	–	–	–	– – – –	D2
DECW A	3	1	(A) ← (A) – 1	–	–	dH	+ + – –	D0
MULU A	19	1	(A) ← (AL) × (TL)	–	–	dH	– – – –	01
DIVU A	21	1	(A) ← (T) / (AL),MOD → (T)	dL	00	00	– – – –	11
ANDW A	3	1	(A) ← (A) ∧ (T)	–	–	dH	+ + R –	63
ORW A	3	1	(A) ← (A) ∨ (T)	–	–	dH	+ + R –	73
XORW A	3	1	(A) ← (A) ∀ (T)	–	–	dH	+ + R –	53
CMP A	2	1	(TL) – (AL)	–	–	–	+ + + +	12
CMPW A	3	1	(T) – (A)	–	–	–	+ + + +	13
RORC A	2	1		–	–	–	+ + – +	03
ROLC A	2	1		–	–	–	+ + – +	02
CMP A,#d8	2	2	(A) – d8	–	–	–	+ + + +	14
CMP A,dir	3	2	(A) – (dir)	–	–	–	+ + + +	15
CMP A,@EP	3	1	(A) – ((EP))	–	–	–	+ + + +	17
CMP A,@IX +off	4	2	(A) – ((IX) +off)	–	–	–	+ + + +	16
CMP A,Ri	3	1	(A) – (Ri)	–	–	–	+ + + +	18 to 1F
DAA	2	1	Decimal adjust for addition	–	–	–	+ + + +	84
DAS	2	1	Decimal adjust for subtraction	–	–	–	+ + + +	94
XOR A	2	1	(A) ← (AL) ∀ (TL)	–	–	–	+ + R –	52
XOR A,#d8	2	2	(A) ← (AL) ∀ d8	–	–	–	+ + R –	54
XOR A,dir	3	2	(A) ← (AL) ∀ (dir)	–	–	–	+ + R –	55
XOR A,@EP	3	1	(A) ← (AL) ∀ ((EP))	–	–	–	+ + R –	57
XOR A,@IX +off	4	2	(A) ← (AL) ∀ ((IX) +off)	–	–	–	+ + R –	56
XOR A,Ri	3	1	(A) ← (AL) ∀ (Ri)	–	–	–	+ + R –	58 to 5F
AND A	2	1	(A) ← (AL) ∧ (TL)	–	–	–	+ + R –	62
AND A,#d8	2	2	(A) ← (AL) ∧ d8	–	–	–	+ + R –	64
AND A,dir	3	2	(A) ← (AL) ∧ (dir)	–	–	–	+ + R –	65

(Continued)

(Continued)

Mnemonic	~	#	Operation	TL	TH	AH	N Z V C	OP code
AND A,@EP	3	1	(A) ← (AL) ∧ ((EP))	–	–	–	+ + R –	67
AND A,@IX +off	4	2	(A) ← (AL) ∧ ((IX) +off)	–	–	–	+ + R –	66
AND A,Ri	3	1	(A) ← (AL) ∧ (Ri)	–	–	–	+ + R –	68 to 6F
OR A	2	1	(A) ← (AL) ∨ (TL)	–	–	–	+ + R –	72
OR A,#d8	2	2	(A) ← (AL) ∨ d8	–	–	–	+ + R –	74
OR A,dir	3	2	(A) ← (AL) ∨ (dir)	–	–	–	+ + R –	75
OR A,@EP	3	1	(A) ← (AL) ∨ ((EP))	–	–	–	+ + R –	77
OR A,@IX +off	4	2	(A) ← (AL) ∨ ((IX) +off)	–	–	–	+ + R –	76
OR A,Ri	3	1	(A) ← (AL) ∨ (Ri)	–	–	–	+ + R –	78 to 7F
CMP dir,#d8	5	3	(dir) – d8	–	–	–	+ + + +	95
CMP @EP,#d8	4	2	((EP)) – d8	–	–	–	+ + + +	97
CMP @IX +off,#d8	5	3	((IX) +off) – d8	–	–	–	+ + + +	96
CMP Ri,#d8	4	2	(Ri) – d8	–	–	–	+ + + +	98 to 9F
INCW SP	3	1	(SP) ← (SP) + 1	–	–	–	– – – –	C1
DECW SP	3	1	(SP) ← (SP) – 1	–	–	–	– – – –	D1

Table 4 Branch Instructions (17 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	N Z V C	OP code
BZ/BEQ rel	3	2	If Z = 1 then PC ← PC + rel	–	–	–	– – – –	FD
BNZ/BNE rel	3	2	If Z = 0 then PC ← PC + rel	–	–	–	– – – –	FC
BC/BLO rel	3	2	If C = 1 then PC ← PC + rel	–	–	–	– – – –	F9
BNC/BHS rel	3	2	If C = 0 then PC ← PC + rel	–	–	–	– – – –	F8
BN rel	3	2	If N = 1 then PC ← PC + rel	–	–	–	– – – –	FB
BP rel	3	2	If N = 0 then PC ← PC + rel	–	–	–	– – – –	FA
BLT rel	3	2	If V ∀ N = 1 then PC ← PC + rel	–	–	–	– – – –	FF
BGE rel	3	2	If V ∀ N = 0 then PC ← PC + rel	–	–	–	– – – –	FE
BBC dir: b,rel	5	3	If (dir: b) = 0 then PC ← PC + rel	–	–	–	– + – –	B0 to B7
BBS dir: b,rel	5	3	If (dir: b) = 1 then PC ← PC + rel	–	–	–	– + – –	B8 to BF
JMP @A	2	1	(PC) ← (A)	–	–	–	– – – –	E0
JMP ext	3	3	(PC) ← ext	–	–	–	– – – –	21
CALLV #vct	6	1	Vector call	–	–	–	– – – –	E8 to EF
CALL ext	6	3	Subroutine call	–	–	–	– – – –	31
XCHW A,PC	3	1	(PC) ← (A),(A) ← (PC) + 1	–	–	dH	– – – –	F4
RET	4	1	Return from subrountine	–	–	–	– – – –	20
RETI	6	1	Return form interrupt	–	–	–	Restore	30

Table 5 Other Instructions (9 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	N Z V C	OP code
PUSHW A	4	1		–	–	–	– – – –	40
POPW A	4	1		–	–	dH	– – – –	50
PUSHW IX	4	1		–	–	–	– – – –	41
POPW IX	4	1		–	–	–	– – – –	51
NOP	1	1		–	–	–	– – – –	00
CLRC	1	1		–	–	–	– – – R	81
SETC	1	1		–	–	–	– – – S	91
CLRI	1	1		–	–	–	– – – –	80
SETI	1	1		–	–	–	– – – –	90

■ INSTRUCTION MAP

L \ H	0	1	2	3	4	5	6	7	8	9	A	B	C	D	E	F
0	NOP	SWAP	RET	RETI	PUSHW A	POPW A	MOV A,ext	MOVW A,PS	CLRI	SETI	CLRB dir:0	BBC dir:0,rel	INCW A	DECW A	JMP @A	MOVW A,PC
1	MULU A	DIVU A	JMP addr16	CALL addr16	PUSHW IX	POPW IX	MOV ext,A	MOVW PS,A	CLRC	SETC	CLRB dir:1	BBC dir:1,rel	INCW SP	DECW SP	MOVW SP,A	MOVW A,SP
2	ROLC A	CMP A	ADDC A	SUBC A	XCH A,T	XOR A	AND A	OR A	MOV @A,T	MOV A,@A	CLRB dir:2	BBC dir:2,rel	INCW IX	DECW IX	MOVW IX,A	MOVW A,IX
3	RORC A	CMPW A	ADDCW A	SUBCW A	XCHW A,T	XORW A	ANDW A	ORW A	MOVW @A,T	MOVW A,@A	CLRB dir:3	BBC dir:3,rel	INCW EP	DECW EP	MOVW EP,A	MOVW A,EP
4	MOV A,#d8	CMP A,#d8	ADDC A,#d8	SUBC A,#d8		XOR A,#d8	AND A,#d8	OR A,#d8	DAA	DAS	CLRB dir:4	BBC dir:4,rel	MOVW A,ext	MOVW ext,A	MOVW A,#d16	XCHW A,PC
5	MOV A,dir	CMP A,dir	ADDC A,dir	SUBC A,dir	MOV dir,A	XOR A,dir	AND A,dir	OR A,dir	MOV dir,#d8	CMP dir,#d8	CLRB dir:5	BBC dir:5,rel	MOVW A,dir	MOVW dir,A	MOVW SP,#d16	XCHW A,SP
6	MOV A,@IX +d	CMP A,@IX +d	ADDC A,@IX +d	SUBC A,@IX +d	MOV @IX +d,A	XOR A,@IX +d	AND A,@IX +d	OR A,@IX +d	MOV @IX +d,#d8	CMP @IX +d,#d8	CLRB dir:6	BBC dir:6,rel	MOVW A,@IX +d	MOVW @IX +d,A	MOVW IX,#d16	XCHW A,IX
7	MOV A,@EP	CMP A,@EP	ADDC A,@EP	SUBC A,@EP	MOV @EP,A	XOR A,@EP	AND A,@EP	OR A,@EP	MOV @EP,#d8	CMP @EP,#d8	CLRB dir:7	BBC dir:7,rel	MOVW A,@EP	MOVW @EP,A	MOVW EP,#d16	XCHW A,EP
8	MOV A,R0	CMP A,R0	ADDC A,R0	SUBC A,R0	MOV R0,A	XOR A,R0	AND A,R0	OR A,R0	MOV R0,#d8	CMP R0,#d8	SETB dir:0	BBS dir:0,rel	INC R0	DEC R0	CALLV #0	BNC rel
9	MOV A,R1	CMP A,R1	ADDC A,R1	SUBC A,R1	MOV R1,A	XOR A,R1	AND A,R1	OR A,R1	MOV R1,#d8	CMP R1,#d8	SETB dir:1	BBS dir:1,rel	INC R1	DEC R1	CALLV #1	BC rel
A	MOV A,R2	CMP A,R2	ADDC A,R2	SUBC A,R2	MOV R2,A	XOR A,R2	AND A,R2	OR A,R2	MOV R2,#d8	CMP R2,#d8	SETB dir:2	BBS dir:2,rel	INC R2	DEC R2	CALLV #2	BP rel
B	MOV A,R3	CMP A,R3	ADDC A,R3	SUBC A,R3	MOV R3,A	XOR A,R3	AND A,R3	OR A,R3	MOV R3,#d8	CMP R3,#d8	SETB dir:3	BBS dir:3,rel	INC R3	DEC R3	CALLV #3	BN rel
C	MOV A,R4	CMP A,R4	ADDC A,R4	SUBC A,R4	MOV R4,A	XOR A,R4	AND A,R4	OR A,R4	MOV R4,#d8	CMP R4,#d8	SETB dir:4	BBS dir:4,rel	INC R4	DEC R4	CALLV #4	BNZ rel
D	MOV A,R5	CMP A,R5	ADDC A,R5	SUBC A,R5	MOV R5,A	XOR A,R5	AND A,R5	OR A,R5	MOV R5,#d8	CMP R5,#d8	SETB dir:5	BBS dir:5,rel	INC R5	DEC R5	CALLV #5	BZ rel
E	MOV A,R6	CMP A,R6	ADDC A,R6	SUBC A,R6	MOV R6,A	XOR A,R6	AND A,R6	OR A,R6	MOV R6,#d8	CMP R6,#d8	SETB dir:6	BBS dir:6,rel	INC R6	DEC R6	CALLV #6	BGE rel
F	MOV A,R7	CMP A,R7	ADDC A,R7	SUBC A,R7	MOV R7,A	XOR A,R7	AND A,R7	OR A,R7	MOV R7,#d8	CMP R7,#d8	SETB dir:7	BBS dir:7,rel	INC R7	DEC R7	CALLV #7	BLT rel

MB89870 Series

■ MASK OPTIONS

No.	Part number	MB89875	MB89P875	MB89PV870
	Specifying procedure	Specify when ordering masking	Set with EPROM programmer	Setting not possible
1	Pull-up resistors P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40 to P47, P50 to P57	Specify by pin (in 2-pin unit for P10 to P17, and in 4-pin unit for P40 to P47)	Specify by pin (in 2-pin unit for P10 to P17, and in 4-pin unit for P40 to P47)	Fixed to without pull-up resistor
2	Power-on reset selection With power-on reset Without power-on reset	Selectable	Selectable	Fixed to with power-on reset
3	Selection of the oscillation stabilization time initial value $2^{18}/F_{CH}$ (Approx. 26.2 ms) $2^{17}/F_{CH}$ (Approx. 13.1 ms) $2^{13}/F_{CH}$ (Approx. 0.8 ms) $2^{4}/F_{CH}$ (Approx. 0 ms)	Selectable	Selectable	Fixed to $2^{18}/F_{CH}$ (Approx. 26.2 ms)
4	Selection either single- or dual-clock system Single clock Dual Clock	Selectable	Selectable	Fixed to dual-clock system
5	Reset pin output With reset output Without reset output	Selectable	Selectable	Fixed to with reset output

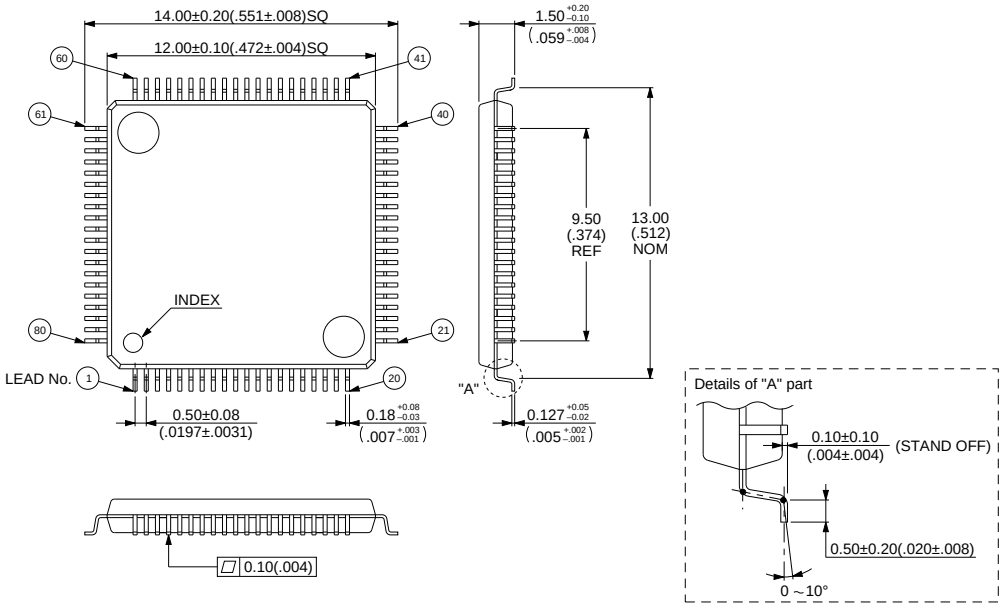
Notes:
- Reset is input asynchronized with the internal clock whether with or without power-on reset.
- P30 to P37 should be set to without pull-up resistor when an A/D conveter is used.
- P10 to P17 should be set to without pull-up resistor when an OP amp is used.
- P40 to P47 and P23 and P24 should be set to without pull-up resistor when an LCD controller/driver is used.

■ ORDERING INFORMATION

Part number	Package	Remarks
MB89PV870CF	80-pin Ceramic MQFP (MQP-80C-P01)	
MB89875PFV MB89P875PFV	80-pin Plastic SQFP (FPT-80P-M05)	
MB89875PF MB89P875PF	80-pin Plastic QFP (FPT-80P-M06)	

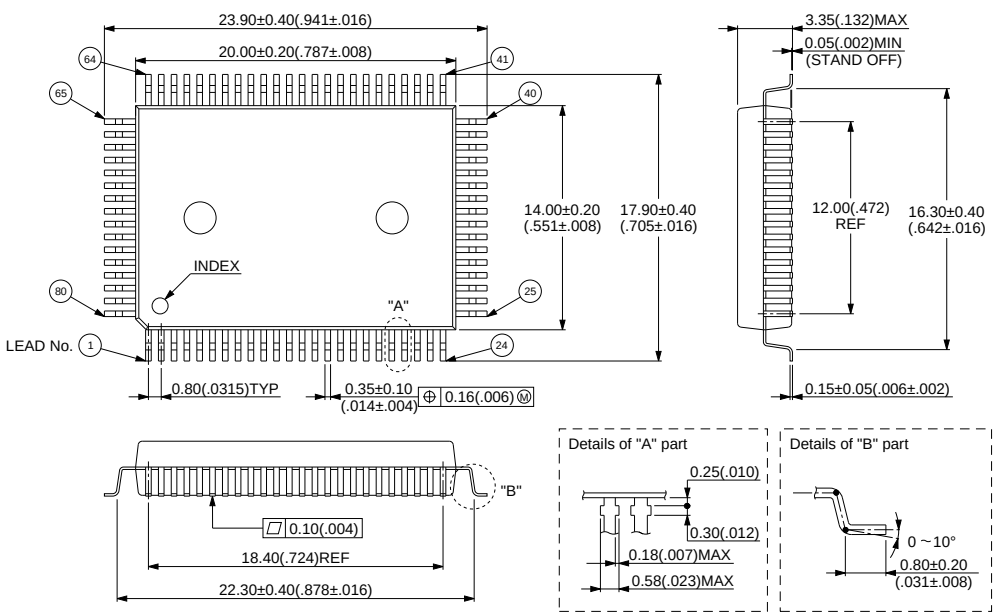
■ PACKAGE DIMENSIONS

80-pin Plastic SQFP
(FPT-80P-M05)



Dimensions in mm (inches)

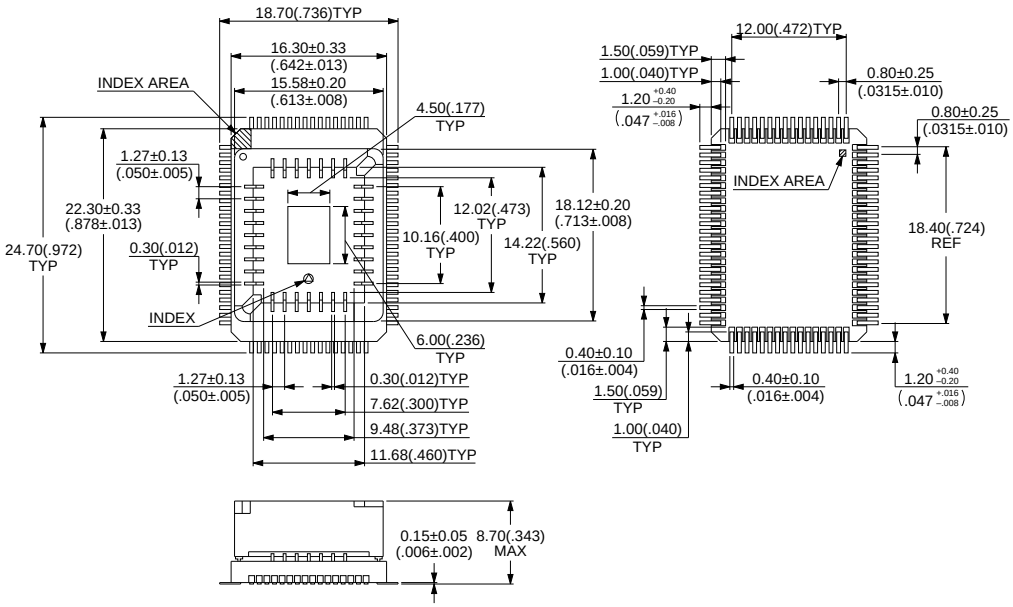
80-pin Plastic QFP
(FPT-80P-M06)



Dimensions in mm (inches)

MB89870 Series

80-pin Ceramic MQFP
(MQF-80C-P01)



Dimensions in mm (inches)

FUJITSU LIMITED

For further information please contact:

Japan
FUJITSU LIMITED
Corporate Global Business Support Division
Electronic Devices
KAWASAKI PLANT, 4-1-1, Kamikodanaka
Nakahara-ku, Kawasaki-shi
Kanagawa 211-88, Japan
Tel: (044) 754-3753
Fax: (044) 754-3329

North and South America
FUJITSU MICROELECTRONICS, INC.
Semiconductor Division
3545 North First Street
San Jose, CA 95134-1804, U.S.A.
Tel: (408) 922-9000
Fax: (408) 432-9044/9045

Europe
FUJITSU MIKROELEKTRONIK GmbH
Am Siebenstein 6-10
63303 Dreieich-Buchschlag
Germany
Tel: (06103) 690-0
Fax: (06103) 690-122

Asia Pacific
FUJITSU MICROELECTRONICS ASIA PTE. LIMITED
#05-08, 151 Lorong Chuan
New Tech Park
Singapore 556741
Tel: (65) 281 0770
Fax: (65) 281 0220

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